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Pages 1 to 54

**INTEGRATED CIRCUITS, SILICON MONOLITHIC,
CMOS 4 x 4 MULTIPORT REGISTER,
WITH 3-STATE OUTPUTS,
BASED ON TYPE 40208B**

ESA/SCC Detail Specification No. 9301/009

SCC

**space components
coordination group**

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DOCUMENTATION CHANGE NOTICE

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APPENDICES (Applicable to specific Manufacturers only)

'A' Agreed Deviations for STMicroelectronics (F)

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1. GENERAL

1.1 SCOPE

This specification details the ratings, physical and electrical characteristics, test and inspection data for a silicon monolithic CMOS 4 x 4 Multiport Register, having fully buffered 3-state outputs, based on Type 40208B. It shall be read in conjunction with ESA/SCC Generic Specification No. 9000, the requirements of which are supplemented herein.

1.2 COMPONENT TYPE VARIANTS

Variants of the basic type integrated circuits specified herein, which are also covered by this specification, are given in Table 1(a).

1.3 MAXIMUM RATINGS

The maximum ratings, which shall not be exceeded at any time during use or storage, applicable to the integrated circuits specified herein, are as scheduled in Table 1(b).

Maximum ratings shall only be exceeded during testing to the extent specified in this specification and when stipulated in Test Methods and Procedures of the applicable ESA/SCC Generic Specification.

1.4 PARAMETER DERATING INFORMATION (FIGURE 1)

Not applicable.

1.5 PHYSICAL DIMENSIONS

As per Figure 2.

1.6 PIN ASSIGNMENT

As per Figure 3(a).

1.7 TRUTH TABLE

As per Figure 3(b).

1.8 CIRCUIT SCHEMATIC

As per Figure 3(c).

1.9 FUNCTIONAL DIAGRAM

As per Figure 3(d).

1.10 HANDLING PRECAUTIONS

These devices are susceptible to damage by electrostatic discharge. Therefore, suitable precautions shall be employed for protection during all phases of manufacture, testing, packaging, shipment and any handling. These components are categorised as Class 1 with a Minimum Critical Path Failure Voltage of 400Volts.

1.11 INPUT PROTECTION NETWORK

Double diode protection shall be incorporated into each input as shown in Figure 3(e).



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PAGE 6
ISSUE 2TABLE 1(a) - TYPE VARIANTS

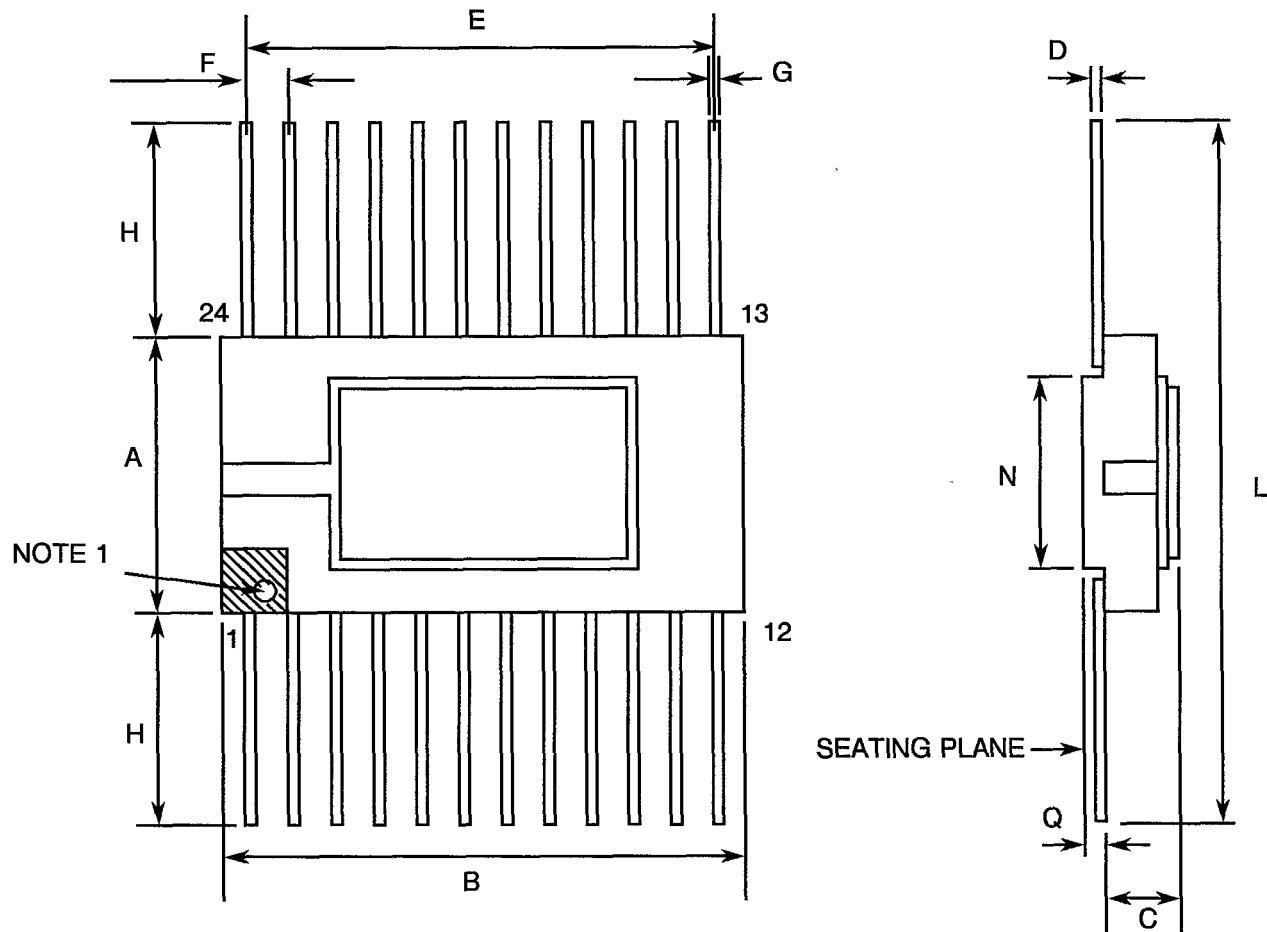
VARIANT	CASE	FIGURE	LEAD MATERIAL AND/OR FINISH
01	FLAT	2(a)	G2 or G8
02	FLAT	2(a)	G4
03	D.I.L.	2(b)	G2 or G8
04	D.I.L.	2(b)	G4
07	CHIP CARRIER	2(c)	2
08	SO CERAMIC	2(d)	G2
09	SO CERAMIC	2(d)	G4

TABLE 1(b) - MAXIMUM RATINGS

NO.	CHARACTERISTICS	SYMBOL	MAXIMUM RATINGS	UNIT	REMARKS
1	Supply Voltage	V_{DD}	-0.5 to +18	V	Note 1
2	Input Voltage	V_{IN}	-0.5 to $V_{DD} + 0.5$	V	Note 2 Power on
3	D.C. Input Current	$\pm I_{IN}$	10	mA	-
4	D.C. Output Current	$\pm I_O$	10	mA	Note 3
5	Device Dissipation	P_D	200	mWdc	Per Package
6	Output Dissipation	P_{DSO}	100	mWdc	Note 4
7	Operating Temperature Range	T_{op}	-55 to +125	°C	-
8	Storage Temperature Range	T_{stg}	-65 to +150	°C	-
9	Soldering Temperature For FP and DIP For CCP	T_{sol}	+300 +245	°C	Note 5 Note 6

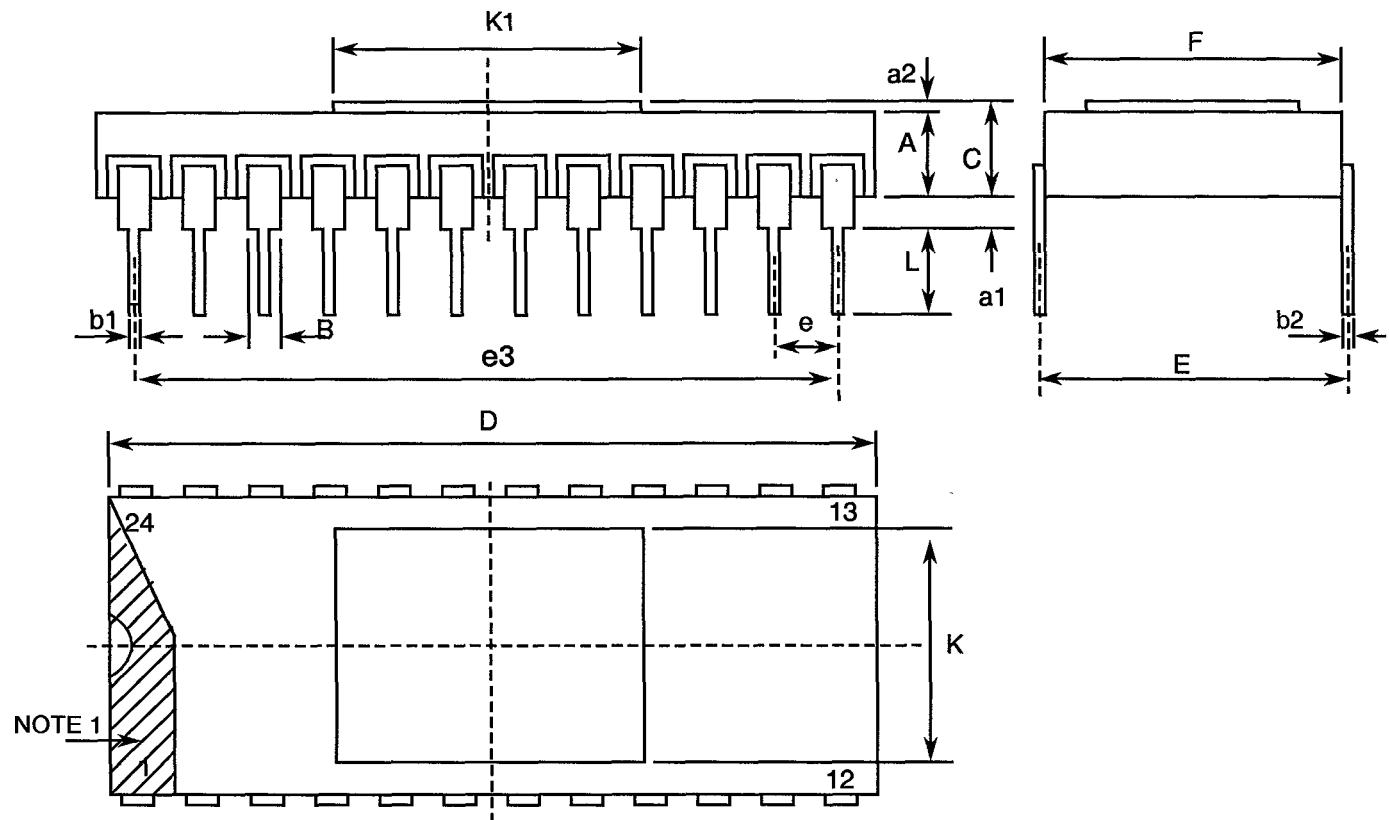
NOTES

1. Device is functional from +3V to +15V with reference to V_{SS} .
2. $V_{DD} + 0.5V$ should not exceed +18V.
3. The maximum output current of any single output.
4. The maximum power dissipation of any single output.
5. Duration 10 seconds maximum at a distance of not less than 1.5mm from the device body and the same lead shall not be resoldered until 3 minutes have elapsed.
6. Duration 30 seconds maximum and the same terminal shall not be resoldered until 3 minutes have elapsed.

FIGURE 2 - PHYSICAL DIMENSIONSFIGURE 2(a) - FLAT PACKAGE, 24-PIN

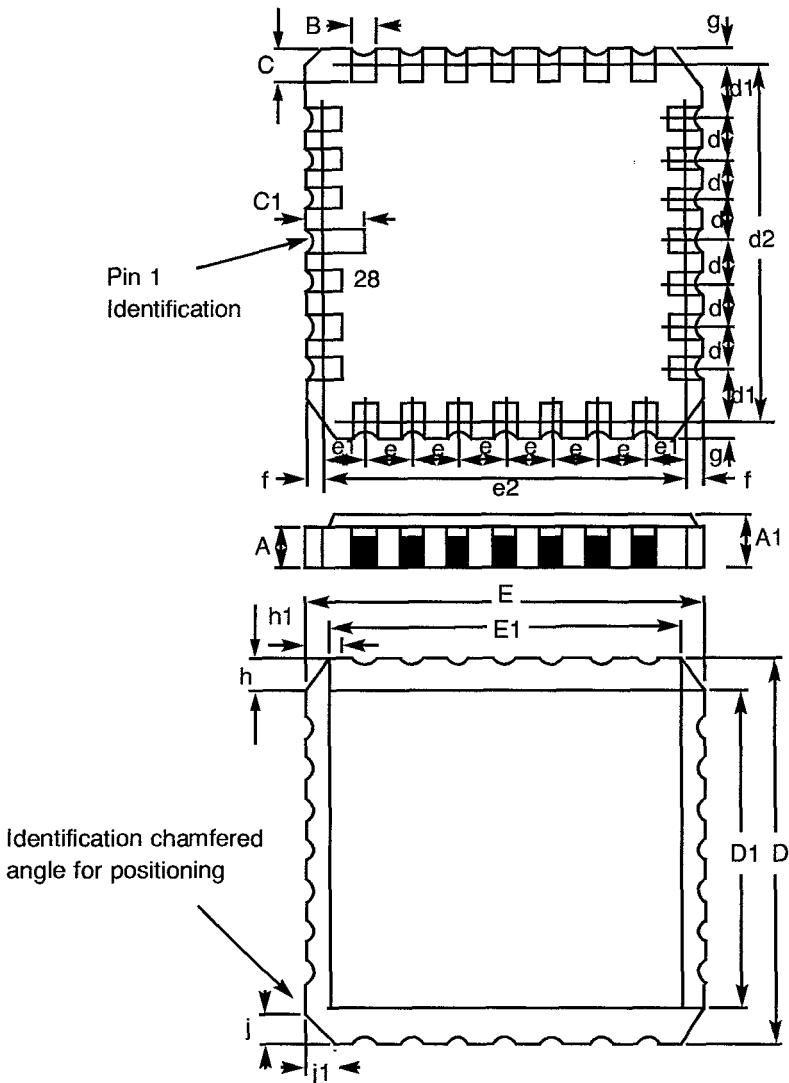
SYMBOL	MILLIMETRES		NOTES
	MIN	MAX	
A	10.70	11.30	
B	15.30	15.70	
C	1.45	1.90	
D	0.23	0.30	
E	13.84	14.10	
F	1.22	1.32	4
G	0.45	0.55	3
H	7.25	8.25	
L	25.00	28.00	
N	7.00	TYPICAL	
Q	0.45	0.55	2

NOTES: See Page 10.

**FIGURE 2 - PHYSICAL DIMENSIONS (CONTINUED)****FIGURE 2(b) - DUAL-IN-LINE PACKAGE, 24-PIN**

SYMBOL	MILLIMETRES		NOTES
	MIN	MAX	
A	1.931	2.387	
a ₁	1.016	1.525	2
a ₂	0.274	0.340	
B	1.274	TYPICAL	3
b ₁	0.407	0.507	3
b ₂	0.229	0.304	3
C	2.205	2.727	
D	30.176	30.784	
E	14.986	15.494	
e	2.413	2.667	4
e ₃	27.813	28.067	
F	14.859	15.367	
L	3.000	3.800	
K	12.600	13.000	
k ₁	12.600	13.000	

NOTES: See Page 10.

**FIGURE 2 - PHYSICAL DIMENSIONS (CONTINUED)****FIGURE 2(c) - CHIP CARRIER - 28-TERMINAL**

DIMENSIONS	MILLIMETRES		NOTES
	MIN	MAX	
A	1.14	1.95	
A ₁	1.63	2.36	
B	0.55	0.72	
C	1.06	1.47	3
C ₁	1.91	2.41	
D	8.67	9.09	
D ₁	7.21	7.52	
d, d ₁	1.27	TYPICAL	4
d ₂	7.62	TYPICAL	
E	8.67	9.09	
E ₁	7.21	7.52	
e, e ₁	1.27	TYPICAL	4
e ₂	7.62	TYPICAL	
f, g	-	0.76	
h, h ₁	1.01	TYPICAL	6
j, j ₁	0.51	TYPICAL	5

NOTES: See Page 10.

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FIGURE 2 - PHYSICAL DIMENSIONS (CONTINUED)

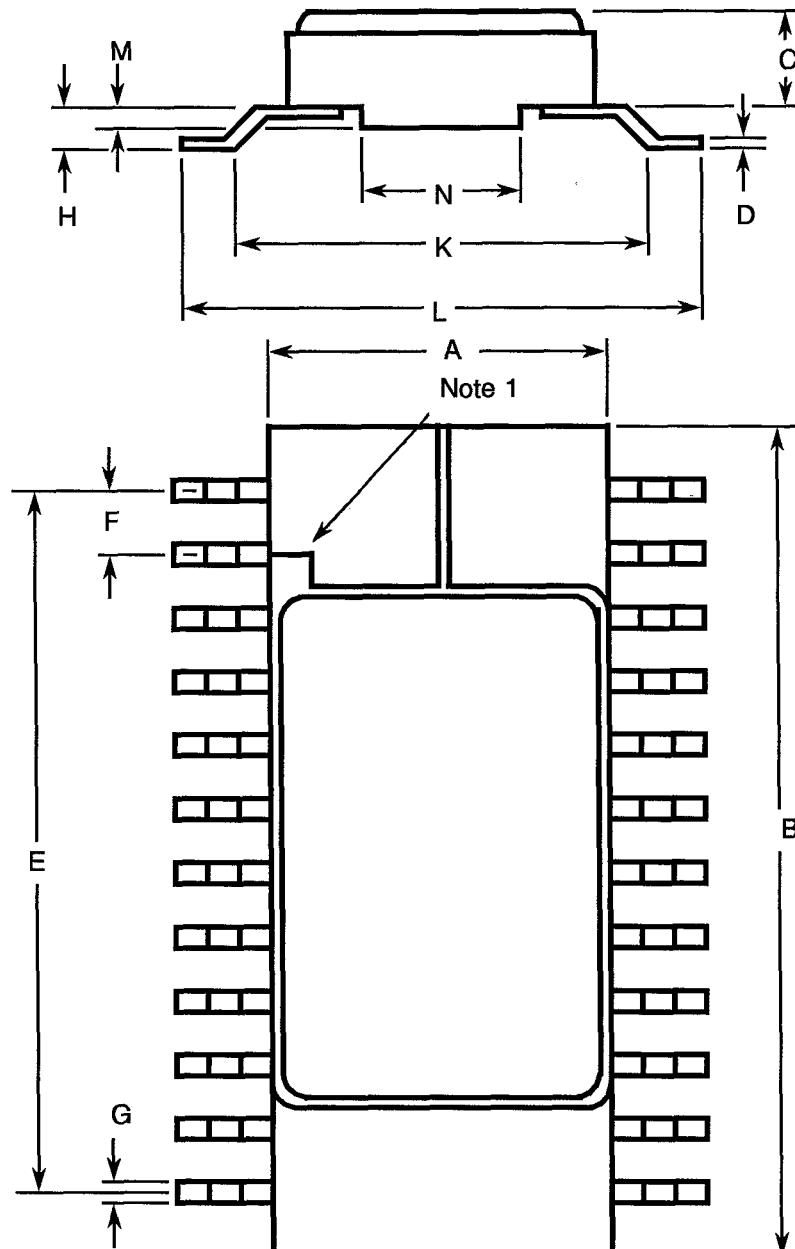
NOTES TO FIGURES 2(a) TO 2(d) INCLUSIVE

1. Index area; a notch, letter, metallised tab or dot shall be located adjacent to Pin 1 or 2 and shall be within the shaded area shown.

For chip carrier packages the index shall be as defined in Figure 2(c).

For SO packages, a dot shall also be located adjacent to Pin 1 on the bottom of the package.

2. The dimension shall be measured from the seating plane to the base plane.
3. All leads or terminals.
4. 24 pin packages : 22 spaces
28 terminal packages : 16 spaces
5. Index corner only.
6. Three non-index corners.

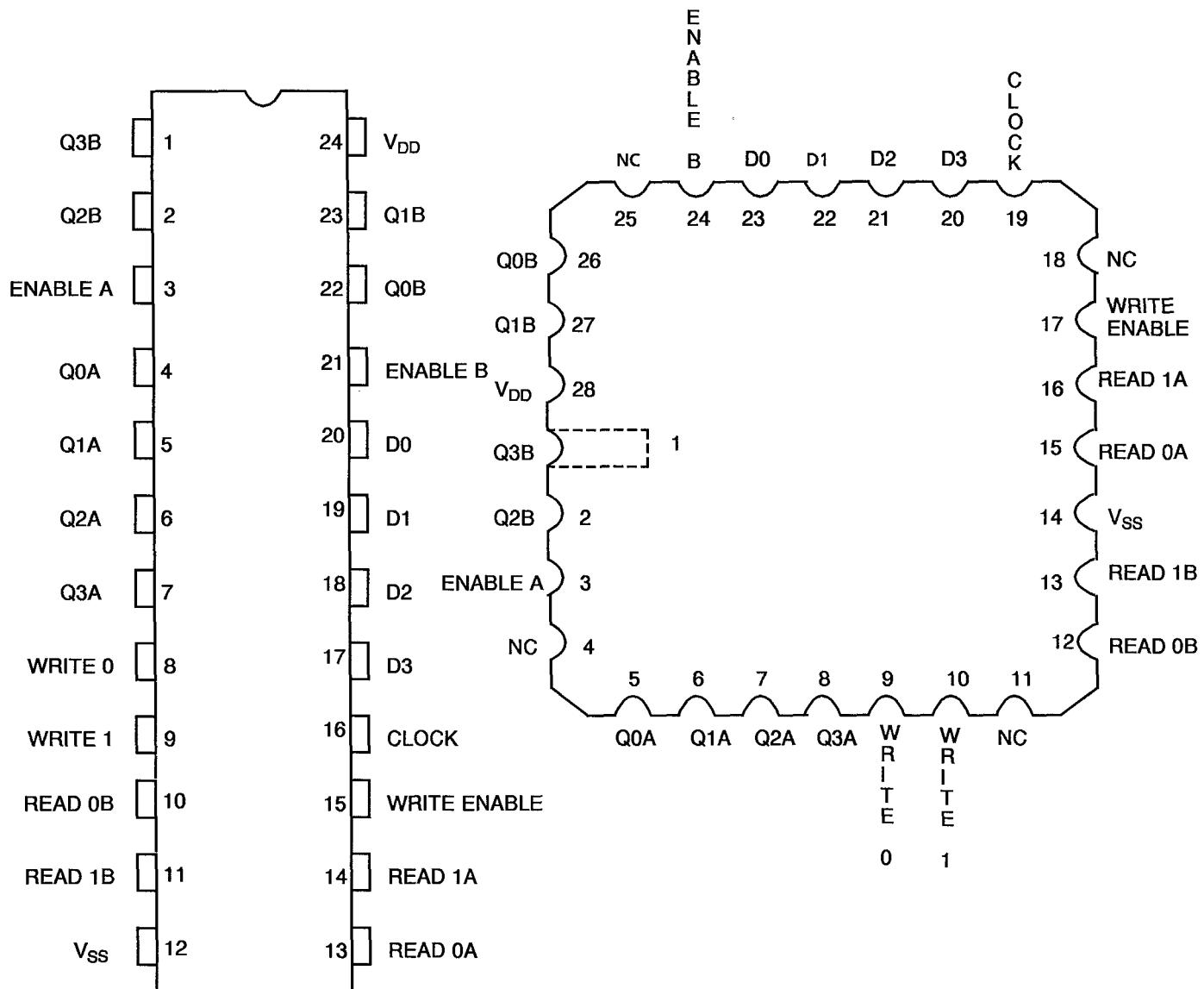
**FIGURE 2 - PHYSICAL DIMENSIONS (CONTINUED)****FIGURE 2(d) - SMALL OUTLINE CERAMIC PACKAGE, 24-PIN**

SYMBOL	MILLIMETRES		NOTES
	MIN.	MAX.	
A	7.30	7.60	
B	15.20	15.60	
C	1.58	1.88	
D	0.17	0.23	3
E	13.82	14.12	
F	1.27 TYPICAL		4
G	0.37	0.47	3
H	0.60	0.90	3
K	9.00 TYPICAL		
L	10	10.65	
M	0.55 TYPICAL		
N	4.31 TYPICAL		

NOTES: See Page 10.

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PAGE 11
ISSUE 2**FIGURE 3(a) - PIN ASSIGNMENT**DUAL-IN-LINE, SO AND FLAT PACKAGESCHIP CARRIER PACKAGETOP VIEWTOP VIEWFLAT PACKAGE, SO AND DUAL-IN-LINE TO CHIP CARRIER PIN ASSIGNMENT

FLAT PACKAGE, SO AND DUAL-IN-LINE PIN OUTS 1 2 3 4 5 6 7 8 9 10 11 12

CHIP CARRIER PIN OUTS 1 2 3 5 6 7 8 9 10 12 13 14

FLAT PACKAGE, SO AND DUAL-IN-LINE PIN OUTS 13 14 15 16 17 18 19 20 21 22 23 24

CHIP CARRIER PIN OUTS 15 16 17 19 20 21 22 23 24 26 27 28

FIGURE 3(b) - TRUTH TABLE

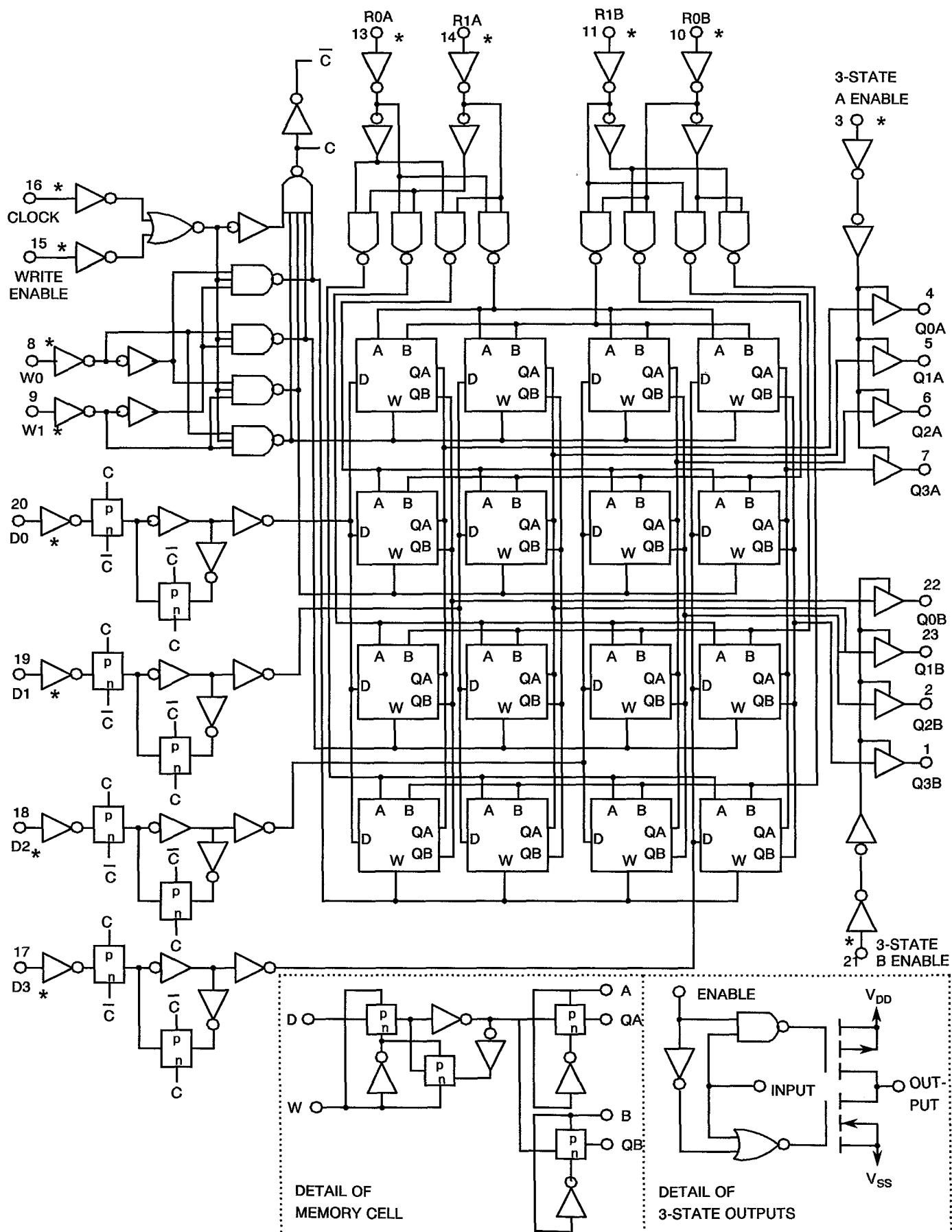
CLOCK	WRITE ENABLE	WRITE 1	WRITE 0	READ 1A	READ 0A	READ 1B	READ 0B	ENABLE A	ENABLE B	D _n	Q _{nA}	Q _{nB}
X	H	S1	S2	S1	S2	S1	S2	H	H	H	H	H
	H	S1	S2	S1	S2	S1	S2	H	H	L	L	L
	X	X	X	X	X	X	X	L	L	X	Z	Z
	H	L	L	L	H	H	L	H	H	D _n to Word 0	Word 1 out	Word 2 out
	L	L	L	L	H	H	L	H	H	Word 0 not Altered	Word 1 out	Word 2 out
	X	X	X	H	L	L	H	H	H	X	Word 2 out	Word 1 out
	X	X	X	X	X	X	X	H	H	X	NC	NC

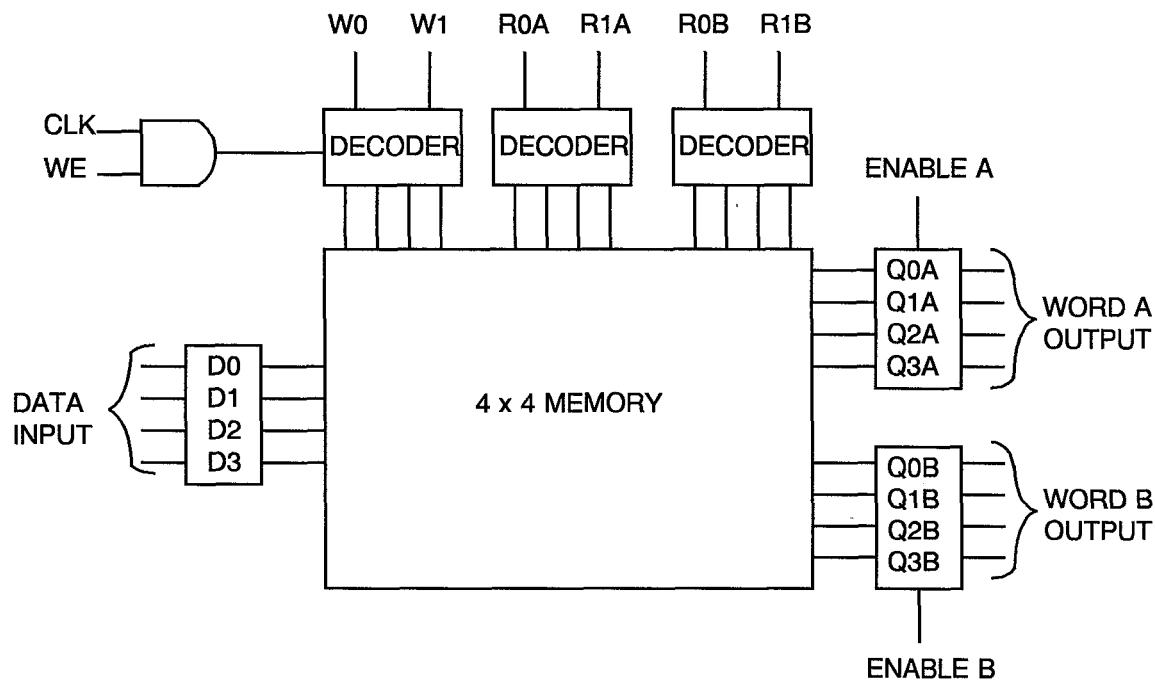
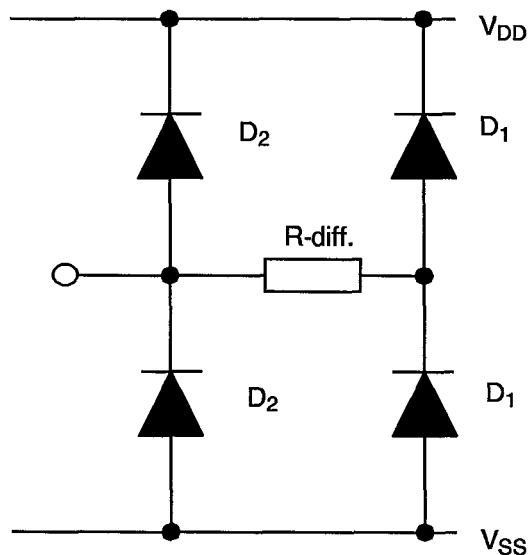
NOTES

1. Logic Level Definitions: L = Low Level, H = High Level, X = Don't Care, Z = High Impedance
2. S1 and S2 refer to input states of either H or L.



FIGURE 3(c) - CIRCUIT SCHEMATIC



**FIGURE 3(d) - FUNCTIONAL DIAGRAM****FIGURE 3(e) - INPUT PROTECTION NETWORK**



2. APPLICABLE DOCUMENTS

The following documents form part of this specification and shall be read in conjunction with it:-

- (a) ESA/SCC Generic Specification No. 9000 for Integrated Circuits.
- (b) MIL-STD-883, Test Methods and Procedures for Micro-electronics.

3. TERMS, DEFINITIONS, ABBREVIATIONS, SYMBOLS AND UNITS

For the purpose of this specification, the terms, definitions, abbreviations, symbols and units specified in ESA/SCC Basic Specification No. 21300 shall apply. In addition, the following abbreviations are used:

V _{IC}	=	Input Clamp Voltage
P _{PSO}	=	Single Output Power Dissipation
CKT	=	Circuit
I _{OZ}	=	Output Leakage Current Third State
t _{PHZ}	=	Propagation Delay, High Output to High Impedance
t _{PZH}	=	Propagation Delay, High Impedance to High Output
t _{PLZ}	=	Propagation Delay, Low Output to High Impedance
t _{PZL}	=	Propagation Delay, High Impedance to Low Output

4. REQUIREMENTS

4.1 GENERAL

The complete requirements for procurement of the integrated circuits specified herein are stated in this specification and ESA/SCC Generic Specification No. 9000 for Integrated Circuits. Deviations from the Generic Specification, applicable to this specification only, are listed in Para. 4.2.

Deviations from the applicable Generic Specification and this Detail Specification, formally agreed with specific Manufacturers on the basis that the alternative requirements are equivalent to the ESA/SCC requirement and do not affect the components' reliability, are listed in the appendices attached to this specification.

4.2 DEVIATIONS FROM GENERIC SPECIFICATION

4.2.1 Deviations from Special In-process Controls

None.

4.2.2 Deviations from Final Production Tests (Chart II)

None.

4.2.3 Deviations from Burn-in Tests (Chart III)

4.2.3.1 Deviations from High Temperature Reverse Bias (H.T.R.B.)

Prior to operating power burn-in, a high temperature reverse bias (H.T.R.B.) screen at +125°C shall be added for the N-Channel and then for the P-Channel in accordance with Tables 5(a) and 5(b) of this specification. Each exposure to H.T.R.B. shall be 72 hours and Table 4 Parameter Drift Values shall be applied at 0 and 144 hours.

4.2.4 Deviations from Qualification, Environmental and Endurance Tests (Chart IV)

None.

**4.2.5 Deviations from Lot Acceptance Tests (Chart V)**

None.

4.3 MECHANICAL REQUIREMENTS**4.3.1 Dimension Check**

The dimensions of the integrated circuits specified herein shall be checked. They shall conform to those shown in Figure 2.

4.3.2 Weight

The maximum weight of the integrated circuits specified herein shall be 4.25 grammes for the dual-in-line package, 1.55 grammes for the flat package, 1.1 grammes for the SO package and 0.79 grammes for the chip carrier package.

4.4 MATERIALS AND FINISHES

The materials shall be as specified herein. Where a definite material is not specified, a material which will enable the integrated circuits specified herein to meet the performance requirements of this specification shall be used. Acceptance or approval of any constituent material does not guarantee acceptance of the finished product.

4.4.1 Case

The case shall be hermetically sealed and have a metal body with hard glass seals or a ceramic body and the lids shall be welded, brazed or preform-soldered.

4.4.2 Lead Material and Finish

For dual-in-line and flat packages, the material shall be Type 'G' with either Type '4' or Type '2 or 8' finish in accordance with ESA/SCC Basic Specification No. 23500. For chip carrier packages the finish shall be Type '2' in accordance with ESA/SCC Basic Specification No. 23500. For SO ceramic packages, the material shall be Type 'G' with either Type '2' or Type '4' finish in accordance with ESA/SCC Basic Specification No. 23500. (See Table 1(a) for Type Variants).

4.5 MARKING**4.5.1 General**

The marking of all components delivered to this specification shall be in accordance with the requirements of ESA/SCC Basic Specification No. 21700. Each component shall be marked in respect of:-

- (a) Lead Identification.
- (b) The SCC Component Number.
- (c) Traceability Information.

4.5.2 Lead Identification

For dual-in-line, flat and SO packages, an index shall be located at the top of the package in the position defined in Note 1 to Figure 2 or, alternatively, a tab may be used to identify Pin No. 1. The pin numbering must be read with the index or tab on the left-hand side. For chip carrier packages, the index shall be as defined by Figure 2(c).



4.5.3 The SCC Component Number

Each component shall bear the SCC Component Number which shall be constituted and marked as follows:

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Detail Specification Number	_____
Type Variant, as applicable	_____
Testing Level (B or C, as appropriate)	_____

4.5.4 Traceability Information

Each component shall be marked in respect of traceability information in accordance with the requirements of ESA/SCC Basic Specification No. 21700.

4.6 ELECTRICAL MEASUREMENTS

4.6.1 Electrical Measurements at Room Temperature

The parameters to be measured in respect of electrical characteristics are scheduled in Table 2. Unless otherwise specified, the measurements shall be performed at $T_{amb} = +22 \pm 3^{\circ}\text{C}$.

4.6.2 Electrical Measurements at High and Low Temperatures

The parameters to be measured at high and low temperatures are scheduled in Table 3. The measurements shall be performed at $T_{amb} = +125(+0.5)^{\circ}\text{C}$ and $-55(+5.0)^{\circ}\text{C}$ respectively.

4.6.3 Circuits for Electrical Measurements

Circuits and functional test sequence for use in performing electrical measurements listed in Tables 2 and 3 of this specification are shown in Figure 4.

4.7 BURN-IN TESTS

4.7.1 Parameter Drift Values

The parameter drift values applicable to burn-in are specified in Table 4 of this specification. Unless otherwise stated, measurements shall be performed at $+22 \pm 3^{\circ}\text{C}$. The parameter drift values (Δ) applicable to the parameters scheduled, shall not be exceeded. In addition to these drift value requirements, the appropriate limit value specified for a given parameter in Table 2 shall not be exceeded.

4.7.2 Conditions for H.T.R.B. and Burn-in

The requirements for H.T.R.B. and Burn-in are specified in Section 7 of ESA/SCC Generic Specification No. 9000. The conditions for H.T.R.B. and Burn-in shall be as specified in Tables 5(a), 5(b) and 5(c) of this specification.

4.7.3 Electrical Circuits for H.T.R.B and Burn-in

Circuits for use in performing the H.T.R.B. and Burn-in tests are shown in Figures 5(a), 5(b) and 5(c) of this specification.



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TABLE 2 - ELECTRICAL MEASUREMENTS AT ROOM TEMPERATURE - d.c. PARAMETERS

NO.	CHARACTERISTICS	SYMBOL	TEST METHOD MIL-STD 883	TEST FIG.	TEST CONDITIONS (PINS UNDER TEST D/F = DIP AND FP C = CCP)	LIMITS		UNIT
						MIN	MAX	
1	Functional Test	-	-	4(a)	Verify Truth Table without Load. $V_{DD} = 3\text{Vdc}$, $V_{SS} = 0\text{Vdc}$ Notes 1 and 2	-	-	-
2	Functional Test	-	-	4(a)	Verify Truth Table without Load. $V_{DD} = 15\text{Vdc}$, $V_{SS} = 0\text{Vdc}$ Notes 1 and 2	-	-	-
3 to 25	Quiescent Current	I_{DD}	3005	4(a)	$V_{IL} = 0\text{Vdc}$, $V_{IH} = 15\text{Vdc}$ $V_{DD} = 15\text{Vdc}$, $V_{SS} = 0\text{Vdc}$ Note 3 (Pin D/F 24) (Pin C 28)	-	1.0	μA
26 to 39	Input Current Low Level	I_{IL}	3009	4(b)	V_{IN} (Under Test) = 0Vdc All Other Inputs: $V_{IN} = 15\text{Vdc}$ $V_{DD} = 15\text{Vdc}$, $V_{SS} = 0\text{Vdc}$ (Pins D/F 3-8-9-10-11-13-14-15-16-17-18-19-20-21) (Pins C 3-9-10-12-13-15-16-17-19-20-21-22-23-24)	-	-50	nA
40 to 53	Input Current High Level	I_{IH}	3010	4(c)	V_{IN} (Under Test) = 15Vdc All Other Inputs: $V_{IN} = 0\text{Vdc}$ $V_{DD} = 15\text{Vdc}$, $V_{SS} = 0\text{Vdc}$ (Pins D/F 3-8-9-10-11-13-14-15-16-17-18-19-20-21) (Pins C 3-9-10-12-13-15-16-17-19-20-21-22-23-24)	-	50	nA
54 to 61	Output Voltage Low Level	V_{OL}	3007	4(d)	V_{IN} (Write Enable & Enable) = 15Vdc Clock Input from Low to High All Other Inputs: $V_{IN} = 0\text{Vdc}$ $V_{OUT} = \text{Open}$ $V_{DD} = 15\text{Vdc}$, $V_{SS} = 0\text{Vdc}$ (Pins D/F 1-2-4-5-6-7-22-23) (Pins C 1-2-5-6-7-8-26-27)	-	0.05	V

NOTES: See Page 24.



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TABLE 2 - ELECTRICAL MEASUREMENTS AT ROOM TEMPERATURE - d.c. PARAMETERS (CONT'D)

NO.	CHARACTERISTICS	SYMBOL	TEST METHOD MIL-STD 883	TEST FIG.	TEST CONDITIONS (PINS UNDER TEST D/F = DIP AND FP C = CCP)	LIMITS		UNIT
						MIN	MAX	
62 to 69	Output Voltage High Level	V _{OH}	3006	4(e)	V _{IN} (Write/Read) = 0Vdc Clock Input from Low to High All Other Inputs: V _{IN} = 15Vdc V _{OUT} = Open V _{DD} = 15Vdc, V _{SS} = 0Vdc (Pins D/F 1-2-4-5-6-7-22-23) (Pins C 1-2-5-6-7-8-26-27)	14.95	-	V
70 to 77	Output Drive Current N-Channel	I _{OL1}	-	4(f)	V _{IN} (Write Enable & Enable) = 5Vdc Clock Input from Low to High All Other Inputs: V _{IN} = 0Vdc V _{OUT} = 0.4Vdc V _{DD} = 5Vdc, V _{SS} = 0Vdc Note 4 (Pins D/F 1-2-4-5-6-7-22-23) (Pins C 1-2-5-6-7-8-26-27)	0.51	-	mA
78 to 85	Output Drive Current N-Channel	I _{OL2}	-	4(f)	V _{IN} (Write Enable & Enable) = 15Vdc Clock Input from Low to High All Other Inputs: V _{IN} = 0Vdc V _{OUT} = 1.5Vdc V _{DD} = 15Vdc, V _{SS} = 0Vdc Note 4 (Pins D/F 1-2-4-5-6-7-22-23) (Pins C 1-2-5-6-7-8-26-27)	3.4	-	mA
86 to 93	Output Drive Current P-Channel	I _{OH1}	-	4(g)	V _{IN} (Write/Read) = 0Vdc Clock Input from Low to High All Other Inputs: V _{IN} = 5Vdc V _{OUT} = 4.6Vdc V _{DD} = 5Vdc, V _{SS} = 0Vdc Note 4 (Pins D/F 1-2-4-5-6-7-22-23) (Pins C 1-2-5-6-7-8-26-27)	-0.51	-	mA

NOTES: See Page 24.



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TABLE 2 - ELECTRICAL MEASUREMENTS AT ROOM TEMPERATURE - d.c. PARAMETERS (CONT'D)

NO.	CHARACTERISTICS	SYMBOL	TEST METHOD MIL-STD 883	TEST FIG.	TEST CONDITIONS (PINS UNDER TEST D/F = DIP AND FP C = CCP)	LIMITS		UNIT
						MIN	MAX	
94 to 101	Output Drive Current P-Channel	I_{OH2}	-	4(g)	V_{IN} (Write/Read) = 0Vdc Clock Input from Low to High All Other Inputs: V_{IN} = 15Vdc V_{OUT} = 13.5Vdc V_{DD} = 15Vdc, V_{SS} = 0Vdc Note 4 (Pins D/F 1-2-4-5-6-7-22-23) (Pins C 1-2-5-6-7-8-26-27)	-3.4	-	mA
102 to 109	Output Leakage Current Third State (1)	I_{OZ1}	-	4(h)	V_{IN} (Enable) = 0Vdc All Other Inputs: V_{IN} = 15Vdc V_{OUT} = 15Vdc V_{DD} = 15Vdc, V_{SS} = 0Vdc (Pins D/F 1-2-4-5-6-7-22-23) (Pins C 1-2-5-6-7-8-26-27)	-	0.4	μA
110 to 117	Output Leakage Current Third State (2)	I_{OZ2}	-	4(h)	V_{IN} (Enable) = 0Vdc All Other Inputs: V_{IN} = 0Vdc V_{OUT} = 0Vdc V_{DD} = 15Vdc, V_{SS} = 0Vdc (Pins D/F 1-2-4-5-6-7-22-23) (Pins C 1-2-5-6-7-8-26-27)	-	-0.4	μA
118	Input Voltage Low Level (Noise Immunity) (Functional Test)	V_{IL1}	-	4(a)	V_{IL} = 1.5Vdc V_{IH} = 3.5Vdc V_{DD} = 5 Vdc, V_{SS} = 0Vdc Note 5 (Pins D/F 1-2-4-5-6-7-22-23) (Pins C 1-2-5-6-7-8-26-27)	4.5	-	V
	Input Voltage High Level (Noise Immunity) (Functional Test)	V_{IH1}	-		-	0.5		

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TABLE 2 - ELECTRICAL MEASUREMENTS AT ROOM TEMPERATURE - d.c. PARAMETERS (CONT'D)

NO.	CHARACTERISTICS	SYMBOL	TEST METHOD MIL-STD 883	TEST FIG.	TEST CONDITIONS (PINS UNDER TEST D/F = DIP AND FP C = CCP)	LIMITS		UNIT
						MIN	MAX	
119	Input Voltage Low Level (Noise Immunity) (Functional Test)	V _{IL2}	-	4(a)	V _{IL} = 4Vdc V _{IH} = 11Vdc V _{DD} = 15Vdc, V _{SS} = 0Vdc Note 5 (Pins D/F 1-2-4-5-6-7-22-23) (Pins C 1-2-5-6-7-8-26-27)	13.5	-	V
	Input Voltage High Level (Noise Immunity) (Functional Test)	V _{IH2}	-			-	1.5	
120	Threshold Voltage N-Channel	V _{THN}	-	4(i)	Clock Input at Ground All Other Inputs: V _{IN} = 5Vdc V _{DD} = 5Vdc, I _{SS} = -10μA (Pin D/F 12) (Pin C 14)	-0.7	-3.0	V
121	Threshold Voltage P-Channel	V _{THP}	-	4(j)	Clock Input at Ground All Other Inputs: V _{IN} = -5Vdc V _{SS} = -5Vdc, I _{DD} = 10μA (Pin D/F 24) (Pin C 28)	0.7	3.0	V
122 to 135	Input Clamp Voltage (to V _{SS})	V _{IC1}	-	4(k)	I _{IN} (Under Test) = -100μA V _{DD} = Open, V _{SS} = 0Vdc All Other Pins Open (Pins D/F 3-8-9-10-11-13-14-15-16-17-18-19-20-21) (Pins C 3-9-10-12-13-15-16-17-19-20-21-22-23-24)	-	-2.0	V
136 to 149	Input Clamp Voltage (to V _{DD})	V _{IC2}	-	4(l)	V _{IN} (Under Test) = 6Vdc V _{SS} = Open, R = 30kΩ; (Pins D/F 3-8-9-10-11-13-14-15-16-17-18-19-20-21) (Pins C 3-9-10-12-13-15-16-17-19-20-21-22-23-24)	3.0	-	V

NOTES: See Page 24.



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TABLE 2 - ELECTRICAL MEASUREMENTS AT ROOM TEMPERATURE - a.c. PARAMETERS

NO.	CHARACTERISTICS	SYMBOL	TEST METHOD MIL-STD 883	TEST FIG.	TEST CONDITIONS (PINS UNDER TEST D/F = DIP AND FP C = CCP)	LIMITS		UNIT
						MIN	MAX	
150 to 163	Input Capacitance	C_{IN}	3012	4(m)	V_{IN} (Not under Test) = 0Vdc $V_{DD} = V_{SS} = 0Vdc$ Note 6 (Pins D/F 3-8-9-10-11-13-14-15-16-17-18-19-20-21) (Pins C 3-9-10-12-13-15-16-17-19-20-21-22-23-24)	-	7.5	pF
164	Propagation Delay Low to High (Clock to Output)	t_{PLH}	3003	4(n)	V_{IN} (Under Test) = Pulse Generator $V_{IH} = 5Vdc, V_{IL} = 0Vdc$ $V_{DD} = 5Vdc, V_{SS} = 0Vdc$ Notes 7 and 8 <u>Pins D/F</u> <u>Pins C</u> 16 to 1 19 to 1	-	670	ns
165	Propagation Delay High to Low (Clock to Output)	t_{PHL}	3003	4(n)	V_{IN} (Under Test) = Pulse Generator $V_{IH} = 5Vdc, V_{IL} = 0Vdc$ $V_{DD} = 5Vdc, V_{SS} = 0Vdc$ Notes 7 and 8 <u>Pins D/F</u> <u>Pins C</u> 16 to 1 19 to 1	-	670	ns
166	Propagation Delay High Impedance to Low Output	t_{PZL}	3003	4(o)	V_{IN} (Under Test) = Pulse Generator $V_{IH} = 5Vdc, V_{IL} = 0Vdc$ $V_{DD} = 5Vdc, V_{SS} = 0Vdc$ Notes 7 and 8 <u>Pins D/F</u> <u>Pins C</u> 21 to 2 24 to 2	-	210	ns
167	Propagation Delay Low Output to High Impedance	t_{PLZ}	3003	4(o)	V_{IN} (Under Test) = Pulse Generator $V_{IH} = 5Vdc, V_{IL} = 0Vdc$ $V_{DD} = 5Vdc, V_{SS} = 0Vdc$ Notes 7 and 8 <u>Pins D/F</u> <u>Pins C</u> 21 to 2 24 to 2	-	210	ns
168	Propagation Delay High Impedance to High Output	t_{PZH}	3003	4(o)	V_{IN} (Under Test) = Pulse Generator $V_{IH} = 5Vdc, V_{IL} = 0Vdc$ $V_{DD} = 5Vdc, V_{SS} = 0Vdc$ Notes 7 and 8 <u>Pins D/F</u> <u>Pins C</u> 21 to 2 24 to 2	-	150	ns

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TABLE 2 - ELECTRICAL MEASUREMENTS AT ROOM TEMPERATURE - a.c. PARAMETERS (CONT'D)

NO.	CHARACTERISTICS	SYMBOL	TEST METHOD MIL-STD 883	TEST FIG.	TEST CONDITIONS (PINS UNDER TEST D/F = DIP AND FP C = CCP)	LIMITS		UNIT
						MIN	MAX	
169	Propagation Delay High Output to High Impedance	t _{PHZ}	3003	4(o)	V _{IN} (Under Test) = Pulse Generator V _{IH} = 5Vdc, V _{IL} = 0Vdc V _{DD} = 5Vdc, V _{SS} = 0Vdc Notes 7 and 8 <u>Pins D/F</u> <u>Pins C</u> 21 to 2 24 to 2	-	150	ns
170	Transition Time Low to High	t _{TLH}	3004	4(n)	V _{IN} (Under Test) = Pulse Generator V _{IN} (All Other Inputs) = 5Vdc V _{DD} = 5Vdc, V _{SS} = 0Vdc Note 7 (Pin D/F 1) (Pin C 1)	-	150	ns
171	Transition Time High to Low	t _{THL}	3004	4(n)	V _{IN} (Under Test) = Pulse Generator V _{IN} (All Other Inputs) = 5Vdc V _{DD} = 5Vdc, V _{SS} = 0Vdc Note 7 (Pin D/F 1) (Pin C 1)	-	150	ns
172	Maximum Clock Frequency	f _(CL)	-	-	Clock = Pulse Generator V _{DD} = 5Vdc, V _{SS} = 0Vdc Notes 7 and 9 (Pin D/F 16) (Pin C 19)	1.5	-	MHz

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TABLE 2 - ELECTRICAL MEASUREMENTS AT ROOM TEMPERATURE (CONT'D)**NOTES**

1. GO-NO-GO Test, each pattern of Test Table 4(a).
 $V_{OH} \geq V_{DD} - 0.5\text{Vdc}$ $V_{OL} \leq 0.5\text{Vdc}$
2. Maximum time to output comparator strobe $300\mu\text{sec}$.
3. Test each pattern of Table 4(a).
4. Interchange of forcing and measuring function is permitted.
5. This is performed as a Functional Test in which extreme V_{IN} conditions are applied and output voltage is measured.
6. Measurement performed on a sample basis LTPD 7, or less, with a Capacitance Bridge connected between each input under test and V_{SS} , only for Lots where LAT Level 2 is to be performed. (For LTPD sampling plan, see Annexe I of ESA/SCC 9000).
7. Measurement performed on a sample basis, LTPD 7 or less, (see Annexe I of ESA/SCC 9000).
8. Before commencement of test, load all stages with Low or High in accordance with Test Table 4(a) and measure propagation time at change.
9. A pulse, having the following conditions, shall be applied to the clock input: $V_P = 0\text{Vdc}$ to $V_{DD}\text{Vdc}$. Maximum clock frequency $f_{(CL)}$ requirement is considered met if proper output stage changes occur with the pulse repetition rate set to that given in the "Limits" column.



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TABLE 3(a) - ELECTRICAL MEASUREMENTS AT HIGH TEMPERATURE, + 125(+ 0-5) °C

NO.	CHARACTERISTICS	SYMBOL	TEST METHOD MIL-STD 883	TEST FIG.	TEST CONDITIONS (PINS UNDER TEST D/F = DIP AND FP C = CCP)	LIMITS		UNIT
						MIN	MAX	
1	Functional Test	-	-	4(a)	Verify Truth Table without Load. $V_{DD} = 3\text{Vdc}$, $V_{SS} = 0\text{Vdc}$ Notes 1 and 2	-	-	-
2	Functional Test	-	-	4(a)	Verify Truth Table without Load. $V_{DD} = 15\text{Vdc}$, $V_{SS} = 0\text{Vdc}$ Notes 1 and 2	-	-	-
3 to 25	Quiescent Current	I_{DD}	3005	4(a)	$V_{IL} = 0\text{Vdc}$, $V_{IH} = 15\text{Vdc}$ $V_{DD} = 15\text{Vdc}$, $V_{SS} = 0\text{Vdc}$ Note 3 (Pin D/F 24) (Pin C 28)	-	30	μA
26 to 39	Input Current Low Level	I_{IL}	3009	4(b)	V_{IN} (Under Test) = 0Vdc All Other Inputs: $V_{IN} = 15\text{Vdc}$ $V_{DD} = 15\text{Vdc}$, $V_{SS} = 0\text{Vdc}$ (Pins D/F 3-8-9-10-11-13- 14-15-16-17-18-19-20-21) (Pins C 3-9-10-12-13-15- 16-17-19-20-21-22-23-24)	-	-100	nA
40 to 53	Input Current High Level	I_{IH}	3010	4(c)	V_{IN} (Under Test) = 15Vdc All Other Inputs: $V_{IN} = 0\text{Vdc}$ $V_{DD} = 15\text{Vdc}$, $V_{SS} = 0\text{Vdc}$ (Pins D/F 3-8-9-10-11-13- 14-15-16-17-18-19-20-21) (Pins C 3-9-10-12-13-15- 16-17-19-20-21-22-23-24)	-	100	nA
54 to 61	Output Voltage Low Level	V_{OL}	3007	4(d)	V_{IN} (Write Enable & Enable) = 15Vdc Clock Input from Low to High All Other Inputs: $V_{IN} = 0\text{Vdc}$ $V_{OUT} = \text{Open}$ $V_{DD} = 15\text{Vdc}$, $V_{SS} = 0\text{Vdc}$ (Pins D/F 1-2-4-5-6-7-22- 23) (Pins C 1-2-5-6-7-8-26-27)	-	0.05	V

NOTES: See Page 24.



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TABLE 3(a) - ELECTRICAL MEASUREMENTS AT HIGH TEMPERATURE, + 125(+ 0-5) °C (CONT'D)

NO.	CHARACTERISTICS	SYMBOL	TEST METHOD MIL-STD 883	TEST FIG.	TEST CONDITIONS (PINS UNDER TEST D/F = DIP AND FP C = CCP)	LIMITS		UNIT
						MIN	MAX	
62 to 69	Output Voltage High Level	V _{OH}	3006	4(e)	V _{IN} (Write/Read) = 0Vdc Clock Input from Low to High All Other Inputs: V _{IN} = 15Vdc V _{OUT} = Open V _{DD} = 15Vdc, V _{SS} = 0Vdc (Pins D/F 1-2-4-5-6-7-22- 23) (Pins C 1-2-5-6-7-8-26-27)	14.95	-	V
70 to 77	Output Drive Current N-Channel	I _{OL1}	-	4(f)	V _{IN} (Write Enable & Enable) = 5Vdc Clock Input from Low to High All Other Inputs: V _{IN} = 0Vdc V _{OUT} = 0.4Vdc V _{DD} = 5Vdc, V _{SS} = 0Vdc Note 4 (Pins D/F 1-2-4-5-6-7-22- 23) (Pins C 1-2-5-6-7-8-26-27)	0.36	-	mA
78 to 85	Output Drive Current N-Channel	I _{OL2}	-	4(f)	V _{IN} (Write Enable & Enable) = 15Vdc Clock Input from Low to High All Other Inputs: V _{IN} = 0Vdc V _{OUT} = 1.5Vdc V _{DD} = 15Vdc, V _{SS} = 0Vdc Note 4 (Pins D/F 1-2-4-5-6-7-22- 23) (Pins C 1-2-5-6-7-8-26-27)	2.4	-	mA
86 to 93	Output Drive Current P-Channel	I _{OH1}	-	4(g)	V _{IN} (Write/Read) = 0Vdc Clock Input from Low to High All Other Inputs: V _{IN} = 5Vdc V _{OUT} = 4.6Vdc V _{DD} = 5Vdc, V _{SS} = 0Vdc Note 4 (Pins D/F 1-2-4-5-6-7-22- 23) (Pins C 1-2-5-6-7-8-26-27)	-0.36	-	mA

NOTES: See Page 24.



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TABLE 3(a) - ELECTRICAL MEASUREMENTS AT HIGH TEMPERATURE, + 125(+ 0-5) °C (CONT'D)

NO.	CHARACTERISTICS	SYMBOL	TEST METHOD MIL-STD 883	TEST FIG.	TEST CONDITIONS (PINS UNDER TEST D/F = DIP AND FP C = CCP)	LIMITS		UNIT
						MIN	MAX	
94 to 101	Output Drive Current P-Channel	I_{OH2}	-	4(g)	V_{IN} (Write/Read) = 0Vdc Clock Input from Low to High All Other Inputs: V_{IN} = 15Vdc V_{OUT} = 13.5Vdc V_{DD} = 15Vdc, V_{SS} = 0Vdc Note 4 (Pins D/F 1-2-4-5-6-7-22-23) (Pins C 1-2-5-6-7-8-26-27)	-2.4	-	mA
102 to 109	Output Leakage Current Third State (1)	I_{OZ1}	-	4(h)	V_{IN} (Enable) = 0Vdc All Other Inputs: V_{IN} = 15Vdc V_{OUT} = 15Vdc V_{DD} = 15Vdc, V_{SS} = 0Vdc (Pins D/F 1-2-4-5-6-7-22-23) (Pins C 1-2-5-6-7-8-26-27)	-	12	μA
110 to 117	Output Leakage Current Third State (2)	I_{OZ2}	-	4(h)	V_{IN} (Enable) = 0Vdc All Other Inputs: V_{IN} = 0Vdc V_{OUT} = 0Vdc V_{DD} = 15Vdc, V_{SS} = 0Vdc (Pins D/F 1-2-4-5-6-7-22-23) (Pins C 1-2-5-6-7-8-26-27)	-	-12	μA
118	Input Voltage Low Level (Noise Immunity) (Functional Test)	V_{IL1}	-	4(a)	V_{IL} = 1.5Vdc V_{IH} = 3.5Vdc V_{DD} = 5 Vdc, V_{SS} = 0Vdc Note 5 (Pins D/F 1-2-4-5-6-7-22-23) (Pins C 1-2-5-6-7-8-26-27)	4.5	-	V
	Input Voltage High Level (Noise Immunity) (Functional Test)	V_{IH1}	-			-	0.5	

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ISSUE 2**TABLE 3(a) - ELECTRICAL MEASUREMENTS AT HIGH TEMPERATURE, + 125(+ 0-5) °C (CONT'D)**

NO.	CHARACTERISTICS	SYMBOL	TEST METHOD MIL-STD 883	TEST FIG.	TEST CONDITIONS (PINS UNDER TEST D/F = DIP AND FP C = CCP)	LIMITS		UNIT
						MIN	MAX	
119	Input Voltage Low Level (Noise Immunity) (Functional Test)	V_{IL2}	-	4(a)	$V_{IL} = 4\text{Vdc}$ $V_{IH} = 11\text{Vdc}$ $V_{DD} = 15\text{Vdc}, V_{SS} = 0\text{Vdc}$ Note 5 (Pins D/F 1-2-4-5-6-7-22-23) (Pins C 1-2-5-6-7-8-26-27)	13.5	-	V
	Input Voltage High Level (Noise Immunity) (Functional Test)	V_{IH2}	-			-	1.5	
120	Threshold Voltage N-Channel	V_{THN}	-	4(i)	Clock Input at Ground All Other Inputs: $V_{IN} = 5\text{Vdc}$ $V_{DD} = 5\text{Vdc}, I_{SS} = -10\mu\text{A}$ (Pin D/F 12) (Pin C 14)	-0.3	-3.5	V
121	Threshold Voltage P-Channel	V_{THP}	-	4(j)	Clock Input at Ground All Other Inputs: $V_{IN} = -5\text{Vdc}$ $V_{SS} = -5\text{Vdc}, I_{DD} = 10\mu\text{A}$ (Pin D/F 24) (Pin C 28)	0.3	3.5	V

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TABLE 3(b) - ELECTRICAL MEASUREMENTS AT LOW TEMPERATURE, -55(+5-0) °C

NO.	CHARACTERISTICS	SYMBOL	TEST METHOD MIL-STD 883	TEST FIG.	TEST CONDITIONS (PINS UNDER TEST D/F = DIP AND FP C = CCP)	LIMITS		UNIT
						MIN	MAX	
1	Functional Test	-	-	4(a)	Verify Truth Table without Load. $V_{DD} = 3\text{Vdc}$, $V_{SS} = 0\text{Vdc}$ Notes 1 and 2	-	-	-
2	Functional Test	-	-	4(a)	Verify Truth Table without Load. $V_{DD} = 15\text{Vdc}$, $V_{SS} = 0\text{Vdc}$ Notes 1 and 2	-	-	-
3 to 25	Quiescent Current	I_{DD}	3005	4(a)	$V_{IL} = 0\text{Vdc}$, $V_{IH} = 15\text{Vdc}$ $V_{DD} = 15\text{Vdc}$, $V_{SS} = 0\text{Vdc}$ Note 3 (Pin D/F 24) (Pin C 28)	-	1.0	μA
26 to 39	Input Current Low Level	I_{IL}	3009	4(b)	V_{IN} (Under Test) = 0Vdc All Other Inputs: $V_{IN} = 15\text{Vdc}$ $V_{DD} = 15\text{Vdc}$, $V_{SS} = 0\text{Vdc}$ (Pins D/F 3-8-9-10-11-13- 14-15-16-17-18-19-20-21) (Pins C 3-9-10-12-13-15- 16-17-19-20-21-22-23-24)	-	-50	nA
40 to 53	Input Current High Level	I_{IH}	3010	4(c)	V_{IN} (Under Test) = 15Vdc All Other Inputs: $V_{IN} = 0\text{Vdc}$ $V_{DD} = 15\text{Vdc}$, $V_{SS} = 0\text{Vdc}$ (Pins D/F 3-8-9-10-11-13- 14-15-16-17-18-19-20-21) (Pins C 3-9-10-12-13-15- 16-17-19-20-21-22-23-24)	-	50	nA
54 to 61	Output Voltage Low Level	V_{OL}	3007	4(d)	V_{IN} (Write Enable & Enable) = 15Vdc Clock Input from Low to High All Other Inputs: $V_{IN} = 0\text{Vdc}$ $V_{OUT} = \text{Open}$ $V_{DD} = 15\text{Vdc}$, $V_{SS} = 0\text{Vdc}$ (Pins D/F 1-2-4-5-6-7-22- 23) (Pins C 1-2-5-6-7-8-26-27)	-	0.05	V

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TABLE 3(b) - ELECTRICAL MEASUREMENTS AT LOW TEMPERATURE, -55(+5-0) °C (CONT'D)

NO.	CHARACTERISTICS	SYMBOL	TEST METHOD MIL-STD 883	TEST FIG.	TEST CONDITIONS (PINS UNDER TEST D/F = DIP AND FP C = CCP)	LIMITS		UNIT
						MIN	MAX	
62 to 69	Output Voltage High Level	V_{OH}	3006	4(e)	V_{IN} (Write/Read) = 0Vdc Clock Input from Low to High All Other Inputs: V_{IN} = 15Vdc V_{OUT} = Open V_{DD} = 15Vdc, V_{SS} = 0Vdc (Pins D/F 1-2-4-5-6-7-22-23) (Pins C 1-2-5-6-7-8-26-27)	14.95	-	V
70 to 77	Output Drive Current N-Channel	I_{OL1}	-	4(f)	V_{IN} (Write Enable & Enable) = 5Vdc Clock Input from Low to High All Other Inputs: V_{IN} = 0Vdc V_{OUT} = 0.4Vdc V_{DD} = 5Vdc, V_{SS} = 0Vdc Note 4 (Pins D/F 1-2-4-5-6-7-22-23) (Pins C 1-2-5-6-7-8-26-27)	0.64	-	mA
78 to 85	Output Drive Current N-Channel	I_{OL2}	-	4(f)	V_{IN} (Write Enable & Enable) = 15Vdc Clock Input from Low to High All Other Inputs: V_{IN} = 0Vdc V_{OUT} = 1.5Vdc V_{DD} = 15Vdc, V_{SS} = 0Vdc Note 4 (Pins D/F 1-2-4-5-6-7-22-23) (Pins C 1-2-5-6-7-8-26-27)	4.2	-	mA
86 to 93	Output Drive Current P-Channel	I_{OH1}	-	4(g)	V_{IN} (Write/Read) = 0Vdc Clock Input from Low to High All Other Inputs: V_{IN} = 5Vdc V_{OUT} = 4.6Vdc V_{DD} = 5Vdc, V_{SS} = 0Vdc Note 4 (Pins D/F 1-2-4-5-6-7-22-23) (Pins C 1-2-5-6-7-8-26-27)	-0.64	-	mA

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TABLE 3(b) - ELECTRICAL MEASUREMENTS AT LOW TEMPERATURE, -55(+5-0) °C (CONT'D)

NO.	CHARACTERISTICS	SYMBOL	TEST METHOD MIL-STD 883	TEST FIG.	TEST CONDITIONS (PINS UNDER TEST D/F = DIP AND FP C = CCP)	LIMITS		UNIT
						MIN	MAX	
94 to 101	Output Drive Current P-Channel	I_{OH2}	-	4(g)	V_{IN} (Write/Read) = 0Vdc Clock Input from Low to High All Other Inputs: V_{IN} = 15Vdc V_{OUT} = 13.5Vdc V_{DD} = 15Vdc, V_{SS} = 0Vdc Note 4 (Pins D/F 1-2-4-5-6-7-22-23) (Pins C 1-2-5-6-7-8-26-27)	-4.2	-	mA
102 to 109	Output Leakage Current Third State (1)	I_{OZ1}	-	4(h)	V_{IN} (Enable) = 0Vdc All Other Inputs: V_{IN} = 15Vdc V_{OUT} = 15Vdc V_{DD} = 15Vdc, V_{SS} = 0Vdc (Pins D/F 1-2-4-5-6-7-22-23) (Pins C 1-2-5-6-7-8-26-27)	-	0.4	μA
110 to 117	Output Leakage Current Third State (2)	I_{OZ2}	-	4(h)	V_{IN} (Enable) = 0Vdc All Other Inputs: V_{IN} = 0Vdc V_{OUT} = 0Vdc V_{DD} = 15Vdc, V_{SS} = 0Vdc (Pins D/F 1-2-4-5-6-7-22-23) (Pins C 1-2-5-6-7-8-26-27)	-	-0.4	μA
118	Input Voltage Low Level (Noise Immunity) (Functional Test)	V_{IL1}	-	4(a)	V_{IL} = 1.5Vdc V_{IH} = 3.5Vdc V_{DD} = 5 Vdc, V_{SS} = 0Vdc Note 5 (Pins D/F 1-2-4-5-6-7-22-23) (Pins C 1-2-5-6-7-8-26-27)	4.5	-	V
	Input Voltage High Level (Noise Immunity) (Functional Test)	V_{IH1}	-			-	0.5	

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ISSUE 2**TABLE 3(b) - ELECTRICAL MEASUREMENTS AT LOW TEMPERATURE, -55(+5-0) °C (CONT'D)**

NO.	CHARACTERISTICS	SYMBOL	TEST METHOD MIL-STD 883	TEST FIG.	TEST CONDITIONS (PINS UNDER TEST D/F = DIP AND FP C = CCP)	LIMITS		UNIT
						MIN	MAX	
119	Input Voltage Low Level (Noise Immunity) (Functional Test)	V_{IL2}	-	4(a)	$V_{IL} = 4\text{Vdc}$ $V_{IH} = 11\text{Vdc}$ $V_{DD} = 15\text{Vdc}, V_{SS} = 0\text{Vdc}$ Note 5 (Pins D/F 1-2-4-5-6-7-22-23) (Pins C 1-2-5-6-7-8-26-27)	13.5	-	V
	Input Voltage High Level (Noise Immunity) (Functional Test)	V_{IH2}	-			-	1.5	
120	Threshold Voltage N-Channel	V_{THN}	-	4(i)	Clock Input at Ground All Other Inputs: $V_{IN} = 5\text{Vdc}$ $V_{DD} = 5\text{Vdc}, I_{SS} = -10\mu\text{A}$ (Pin D/F 12) (Pin C 14)	-0.7	-3.5	V
121	Threshold Voltage P-Channel	V_{THP}	-	4(j)	Clock Input at Ground All Other Inputs: $V_{IN} = -5\text{Vdc}$ $V_{SS} = -5\text{Vdc}, I_{DD} = 10\mu\text{A}$ (Pin D/F 24) (Pin C 28)	0.7	3.5	V

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FIGURE 4 - CIRCUITS FOR ELECTRICAL MEASUREMENTS

FIGURE 4(a) - FUNCTIONAL AND QUIESCENT CURRENT TEST TABLE

PATTERN NO.	PIN NUMBERS																							I _{DD} TEST NO.	D.C. SUPPLY 12 24	
	1	2	3	4	5	6	7	8	9	10	11	13	14	15	16	17	18	19	20	21	22	23				
0	X	X	1	X	X	X	X	0	0	0	0	0	0	0	1	0	0	0	0	0	1	X	X	0	V _{DD}	
1	0	0	1	0	0	0	0	0	0	0	0	0	0	0	1	1	0	0	0	0	1	0	0	1		
2	0	0	1	0	0	0	0	1	0	0	0	0	0	0	1	0	0	0	0	0	0	1	0	0		
3	0	0	1	0	0	0	0	1	0	0	0	0	0	0	1	1	0	0	0	0	0	1	0	0		
4	0	0	1	0	0	0	0	0	1	0	0	0	0	0	1	0	0	0	0	0	0	1	0	0		
5	0	0	1	0	0	0	0	0	1	0	0	0	0	0	1	1	0	0	0	0	0	1	0	0		
6	0	0	1	0	0	0	0	1	1	0	0	0	0	0	1	0	0	0	0	0	0	1	0	0		
7	0	0	1	0	0	0	0	1	1	0	0	0	0	0	1	1	0	0	0	0	0	1	0	0		
8	0	0	1	0	0	0	0	0	0	0	0	0	0	0	1	0	0	0	0	0	0	1	0	0		
9	0	0	1	0	0	0	0	1	0	1	1	0	0	0	0	1	1	1	1	1	1	0	0			
10	0	0	1	0	0	0	0	1	0	0	1	1	0	0	1	1	1	1	1	1	1	0	0	3		
11	0	0	1	0	0	0	0	1	1	1	0	0	1	0	0	0	0	0	0	1	1	0	0	4		
12	0	0	1	0	0	0	0	1	1	0	0	1	1	0	1	0	0	0	1	1	0	0				
12a	0	0	1	0	0	0	0	1	1	0	0	1	1	0	0	0	0	0	0	1	1	0	0			
13	0	0	1	0	0	0	0	0	0	0	0	0	0	0	1	0	0	0	0	0	1	1	0	0		
14	0	0	1	1	0	0	0	0	0	0	0	0	0	0	1	1	0	0	0	1	1	1	0	5		
15	0	0	1	0	0	0	0	0	1	0	1	0	1	0	0	0	0	0	1	1	0	0				
16	0	0	1	0	0	0	0	0	0	0	0	1	0	1	1	0	0	0	1	1	1	0	0			
17	0	0	1	0	0	0	0	0	0	1	1	1	1	1	1	0	0	0	1	1	1	0	0			
18	0	0	1	1	1	0	0	0	1	0	0	0	1	1	0	0	1	1	1	1	0	0				
19	0	0	1	0	0	0	0	0	0	1	1	0	1	0	0	0	1	1	1	1	0	0				
20	0	0	1	0	0	0	0	0	0	1	1	0	1	1	0	0	1	1	1	1	0	0				
21	0	0	1	0	0	0	0	0	0	0	1	1	1	1	0	0	1	1	1	1	1	1	1	6		
22	0	0	1	0	0	0	0	0	0	1	1	0	1	1	0	1	1	1	1	1	1	0	0	7		
23	0	0	1	0	0	0	0	0	0	1	1	0	1	1	0	0	1	1	1	1	1	0	0	8		
24	0	1	1	0	0	0	0	0	0	0	1	1	1	1	0	1	1	1	1	1	1	1	1			
25	0	0	1	1	1	0	0	0	1	0	0	0	1	0	1	1	1	1	1	1	1	1	0			
26	0	0	1	0	0	0	0	0	1	1	0	1	1	1	1	1	1	1	1	1	1	1	0			
27	1	1	1	0	0	0	0	0	0	0	1	1	1	1	0	1	1	1	1	1	1	1	1			
28	0	0	1	1	1	1	0	0	1	0	0	0	1	0	0	0	0	1	1	1	0	0	9			
29	0	0	1	0	0	0	0	1	0	0	1	1	0	1	0	0	0	0	1	1	0	0		10		
30	1	1	1	1	1	1	1	0	0	0	0	0	0	1	1	0	0	0	1	1	1	1	1			
31	0	0	1	1	0	0	0	1	0	1	0	1	0	1	0	0	0	0	1	1	1	0				
32	0	0	1	0	0	0	0	1	0	0	1	0	1	1	0	0	0	1	1	1	1	0	0			
33	0	0	1	0	0	0	0	1	0	1	1	1	1	0	0	0	1	1	1	1	0	0				
34	1	1	1	1	1	1	1	0	0	0	0	0	0	1	1	0	0	1	1	1	1	1	1			
35	0	0	1	1	1	0	0	1	0	1	0	1	0	1	0	0	0	1	1	1	1	1	1	11		
36	0	0	1	0	0	0	0	1	0	0	1	0	1	1	0	0	1	1	1	1	1	1	0	0		
37	0	0	1	0	0	0	0	1	0	1	1	1	1	1	0	0	1	1	1	1	1	1	0	0		
38	1	1	1	1	1	1	1	1	0	0	0	0	0	1	1	0	1	1	1	1	1	1	1	12		
39	0	1	1	1	1	1	0	1	0	1	0	1	0	1	0	0	1	1	1	1	1	1	1	1		
40	0	0	1	0	0	0	0	1	0	0	1	0	1	1	0	1	1	1	1	1	1	1	0	0		
41	0	0	1	0	0	0	0	1	0	1	1	1	1	1	0	1	1	1	1	1	1	1	0	0		

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ISSUE 2**FIGURE 4 - CIRCUITS FOR ELECTRICAL MEASUREMENTS (CONTINUED)****FIGURE 4(a) - FUNCTIONAL AND QUIESCENT CURRENT TEST TABLE (CONTINUED)**

PATTERN NO.	PIN NUMBERS																							IDD TEST NO.	D.C. SUPPLY	
	1	2	3	4	5	6	7	8	9	10	11	13	14	15	16	17	18	19	20	21	22	23	12	24		
42	1	1	1	1	1	1	1	1	0	0	0	0	0	1	1	1	1	1	1	1	1	1	1	0	V _{DD}	
43	1	1	1	1	1	1	1	1	0	1	0	1	0	1	0	1	1	1	1	1	1	1	1			
44	0	0	1	0	0	0	0	1	0	0	1	0	1	1	0	0	0	0	1	1	0	0				
45	0	0	1	0	0	0	0	0	1	1	1	1	1	1	0	0	0	0	1	1	0	0	13			
46	1	1	1	1	1	1	1	0	1	0	0	0	0	1	1	0	0	0	1	1	1	1	1	14		
47	1	1	1	1	1	1	1	0	1	1	0	1	0	1	0	0	0	0	1	1	1	1	1			
48	0	0	1	1	0	0	0	0	1	0	1	0	1	1	0	0	0	0	1	1	1	1	0			
49	0	0	1	0	0	0	0	0	1	1	1	1	1	1	0	0	0	0	1	1	1	0	0			
50	1	1	1	1	1	1	1	0	1	0	0	0	0	1	1	0	0	1	1	1	1	1	1			
51	1	1	1	1	1	1	1	0	1	1	0	1	0	1	0	0	0	1	1	1	1	1	1	15		
52	0	0	1	1	1	0	0	0	1	0	1	0	1	1	0	0	1	1	1	1	1	1	1			
53	0	0	1	0	0	0	0	0	1	1	1	1	1	1	0	0	1	1	1	1	1	0	0			
54	1	1	1	1	1	1	1	0	1	0	0	0	0	1	1	0	1	1	1	1	1	1	1			
55	1	1	1	1	1	1	1	0	1	1	0	1	0	1	0	0	1	1	1	1	1	1	1			
56	0	1	1	1	1	1	0	0	1	0	1	0	1	1	0	1	1	1	1	1	1	1	1	16		
57	0	0	1	0	0	0	0	0	1	1	1	1	1	1	0	1	1	1	1	1	1	1	0			
58	1	1	1	1	1	1	1	0	1	0	0	0	0	1	1	1	1	1	1	1	1	1	1			
59	1	1	1	1	1	1	1	0	1	1	0	1	0	1	0	1	1	1	1	1	1	1	1			
60	1	1	1	1	1	1	1	0	1	0	1	0	1	1	0	0	0	1	1	1	1	1	1			
61	0	0	1	0	0	0	0	1	1	1	1	1	1	1	0	0	0	0	1	1	0	0	17			
62	1	1	1	1	1	1	1	1	1	0	0	0	0	1	1	0	0	0	1	1	1	1	1			
63	1	1	1	1	1	1	1	1	1	0	1	0	1	0	1	0	0	0	1	1	1	1	1			
64	1	1	1	1	1	1	1	1	1	0	1	0	1	1	0	0	0	1	1	1	1	1	1			
65	0	0	1	1	0	0	0	1	1	1	1	1	1	1	0	0	0	1	1	1	1	0	18			
66	1	1	1	1	1	1	1	1	1	0	0	0	0	1	1	0	0	1	1	1	1	1	1			
67	1	1	1	1	1	1	1	1	1	1	0	1	0	1	0	0	0	1	1	1	1	1	1			
68	1	1	1	1	1	1	1	1	1	0	1	0	1	1	0	0	1	1	1	1	1	1	1	19		
69	0	0	1	1	1	0	0	1	1	1	1	1	1	1	0	0	1	1	1	1	1	1	1			
70	1	1	1	1	1	1	1	1	1	0	0	0	0	1	1	0	1	1	1	1	1	1	1			
71	1	1	1	1	1	1	1	1	1	1	0	1	0	1	0	0	1	1	1	1	1	1	1	20		
72	1	1	1	1	1	1	1	0	1	1	0	1	0	1	1	0	1	1	1	1	1	1	1			
73	0	1	1	1	1	1	0	1	1	1	1	1	1	1	0	1	1	1	1	1	1	1	1			
74	1	1	1	1	1	1	1	1	1	0	0	0	0	1	1	1	1	1	1	1	1	1	1	21		
75	1	1	1	1	1	1	1	1	1	1	0	1	0	1	0	1	1	1	1	1	1	1	1			

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ISSUE 2**FIGURE 4 - CIRCUITS FOR ELECTRICAL MEASUREMENTS (CONTINUED)****FIGURE 4(a) - FUNCTIONAL AND QUIESCENT CURRENT TEST TABLE (CONTINUED)**

PATTERN NO.	PIN NUMBERS																							I _{DD} TEST NO.	D.C. SUPPLY
	1	2	3	4	5	6	7	8	9	10	11	13	14	15	16	17	18	19	20	21	22	23			
76	1	1	1	1	1	1	1	1	1	0	1	0	1	1	0	0	1	1	1	1	1	1	1	0	V _{DD}
77	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	0	0	1	1	1	1	1	1	1	
78	1	1	1	1	1	1	1	1	1	0	0	0	0	1	1	0	1	1	1	1	1	1	1		
79	1	1	1	1	1	1	1	1	1	1	0	1	0	1	0	0	1	1	1	1	1	1	1		
80	1	1	1	1	1	1	1	1	1	0	1	0	1	1	0	0	0	1	1	1	1	1	1		
81	0	1	1	1	1	1	0	1	1	1	1	1	1	1	0	0	0	1	1	1	1	1	1		
82	1	1	1	1	1	1	1	1	1	0	0	0	0	1	1	0	0	1	1	1	1	1	1		
83	1	1	1	1	1	1	1	1	1	1	0	1	0	1	0	0	0	1	1	1	1	1	1		
84	1	1	1	1	1	1	1	1	1	0	1	0	1	1	0	0	0	0	1	1	1	1	1		
85	0	0	1	1	1	0	0	1	1	1	1	1	1	1	0	0	0	0	1	1	1	1	1		
86	1	1	1	1	1	1	1	1	1	0	0	0	0	1	1	0	0	0	1	1	1	1	1		
87	1	1	1	1	1	1	1	1	1	1	0	1	0	1	0	0	0	0	1	1	1	1	1		
88	1	1	1	1	1	1	1	1	1	1	0	1	0	1	1	0	0	0	0	1	1	1	1		
89	0	0	1	1	0	0	0	1	1	1	1	1	1	1	0	0	0	0	0	1	1	0			
90	1	1	1	1	1	1	1	1	1	0	0	0	0	1	1	0	0	0	0	1	1	1	1		
91	1	1	1	1	1	1	1	1	1	1	0	1	0	1	0	0	0	0	1	1	1	1	1		
92	1	1	1	1	1	1	1	1	1	0	1	0	1	1	0	1	1	1	0	1	1	1	1		
93	0	0	1	0	0	0	0	0	1	1	1	1	1	1	0	1	1	1	0	1	0	0			
94	1	1	1	1	1	1	1	0	1	0	0	0	0	1	1	1	1	1	0	1	1	1	1		
95	1	1	1	1	1	1	1	0	1	1	0	1	0	1	0	1	1	1	0	1	1	1	1		
96	1	1	1	0	1	1	1	0	1	0	1	0	1	1	0	1	1	0	0	1	0	1	1		
97	0	0	1	0	0	0	0	0	1	1	1	1	1	1	0	1	1	0	0	1	0	0			
98	1	1	1	1	1	1	1	0	1	0	0	0	0	1	1	1	1	0	0	1	1	1	1		
99	1	1	1	1	1	1	1	0	1	1	0	1	0	1	0	1	1	0	0	1	1	1	1		
100	1	1	1	0	0	1	1	0	1	0	1	0	1	1	0	1	0	0	0	1	0	0			
101	0	0	1	0	0	0	0	0	1	1	1	1	1	1	0	1	0	0	0	1	0	0			
102	1	1	1	1	1	1	1	0	1	0	0	0	0	1	1	1	0	0	0	1	1	1	1		
103	1	1	1	1	1	1	1	0	1	1	0	1	0	1	0	1	0	0	0	1	1	1	1		
104	1	0	1	0	0	0	1	0	1	0	1	0	1	1	0	0	0	0	0	1	0	0			
105	0	0	1	0	0	0	0	0	1	1	1	1	1	1	0	0	0	0	0	1	0	0			
106	1	1	1	1	1	1	1	0	1	0	0	0	1	1	0	0	0	0	1	1	1	1	1		
107	1	1	1	1	1	1	1	1	0	1	1	0	1	0	1	0	0	0	0	1	1	1	1		

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ISSUE 2**FIGURE 4 - CIRCUITS FOR ELECTRICAL MEASUREMENTS (CONTINUED)****FIGURE 4(a) - FUNCTIONAL AND QUIESCENT CURRENT TEST TABLE (CONTINUED)**

PATTERN NO.	PIN NUMBERS																							I _{DD} TEST NO.	D.C. SUPPLY			
	1	2	3	4	5	6	7	8	9	10	11	13	14	15	16	17	18	19	20	21	22	23	12	24				
108	0	0	1	0	0	0	0	0	1	0	1	0	1	1	0	0	1	1	1	1	1	0	0	0	0	0	V _{DD}	
109	0	0	1	0	0	0	0	1	0	1	1	1	1	1	0	0	1	1	1	1	1	0	0	0	0	0		
110	1	1	1	1	1	1	1	1	0	0	0	0	0	1	1	0	1	1	1	1	1	1	1	1	1	1		
111	0	1	1	1	1	1	0	1	0	1	0	1	0	1	0	0	1	1	1	1	1	1	1	1	1	1		
112	0	0	1	0	0	0	0	1	0	0	1	0	1	1	0	0	0	1	1	1	1	0	0	0	0	0		
113	0	0	1	0	0	0	0	1	0	1	1	1	1	1	0	0	0	1	1	1	1	0	0	0	0	0		
114	1	1	1	1	1	1	1	1	0	0	0	0	0	0	1	1	0	0	1	1	1	1	1	1	1	1		
115	0	0	1	1	1	0	0	1	0	1	0	1	0	1	0	0	0	1	1	1	1	1	1	1	1	1		
116	0	0	1	0	0	0	0	1	0	0	1	0	1	1	0	0	0	0	1	1	0	0	0	0	0	0		
117	0	0	1	0	0	0	0	1	0	1	1	1	1	1	0	0	0	0	1	1	0	0	0	0	0	0		
118	1	1	1	1	1	1	1	1	0	0	0	0	0	0	1	1	0	0	0	0	1	1	1	1	1	1		
119	0	0	1	1	0	0	0	1	0	1	0	1	0	1	0	0	0	0	1	1	1	1	0	0	0	0		
120	0	0	1	0	0	0	0	1	0	0	1	0	1	1	0	0	0	0	0	0	1	0	0	0	0	0		
121	0	0	1	0	0	0	0	1	0	1	1	1	1	1	0	0	0	0	0	0	1	0	0	0	0	0		
122	1	1	1	1	1	1	1	1	0	0	0	0	0	0	1	1	0	0	0	0	1	1	1	1	1	1		
123	0	0	1	0	0	0	0	1	0	1	0	1	0	1	0	0	0	0	0	1	0	0	0	0	0	0		
124	0	0	1	0	0	0	0	1	0	0	1	0	1	1	0	1	1	1	0	1	0	0	0	0	0	0		
125	0	0	1	0	0	0	0	0	0	1	1	1	1	1	0	1	1	1	0	1	0	0	0	0	0	0		
126	1	1	1	0	1	1	1	0	0	0	0	0	0	0	1	1	1	1	1	1	1	0	1	0	1	0		
127	0	0	1	0	0	0	0	0	0	1	0	1	0	1	0	1	1	1	1	0	1	0	0	0	0	0		
128	0	0	1	0	0	0	0	0	0	0	0	1	0	1	1	0	1	1	0	0	1	0	0	0	0	0		
129	0	0	1	0	0	0	0	0	0	1	1	1	1	1	0	1	1	0	0	1	0	0	0	1	0	0		
130	1	1	1	0	0	1	1	0	0	0	0	0	0	1	1	1	1	1	0	0	1	0	0	0	0	0		
131	0	0	1	0	0	0	0	0	0	1	0	1	0	1	0	1	1	0	0	1	0	0	0	1	0	0		
132	0	0	1	0	0	0	0	0	0	0	1	0	1	1	0	1	0	1	0	0	0	1	0	0	0	0		
133	0	0	1	0	0	0	0	0	0	1	1	1	1	1	0	1	0	0	0	1	0	0	0	1	0	0		
134	1	0	1	0	0	0	1	0	0	0	0	0	0	0	1	1	1	1	0	0	0	1	0	0	0	0		
135	0	0	1	0	0	0	0	0	0	1	0	1	0	1	0	1	0	0	0	1	0	0	0	1	0	0		
136	0	0	1	0	0	0	0	0	0	0	1	0	1	1	0	0	0	0	0	0	1	0	0	0	0	0		
137	0	0	1	0	0	0	0	0	0	1	1	1	1	1	0	0	0	0	0	0	1	0	0	0	0	0		
138	0	0	1	0	0	0	0	0	0	0	0	0	0	0	1	1	0	0	0	0	0	1	0	0	0	0		
139	0	0	1	0	0	0	0	0	0	1	0	1	0	1	0	0	0	0	0	0	1	0	0	0	0	0		
140	0	0	1	0	0	0	0	0	0	0	1	0	1	1	0	1	1	1	1	1	1	0	0	0	0	0		

NOTES: See Page 37.



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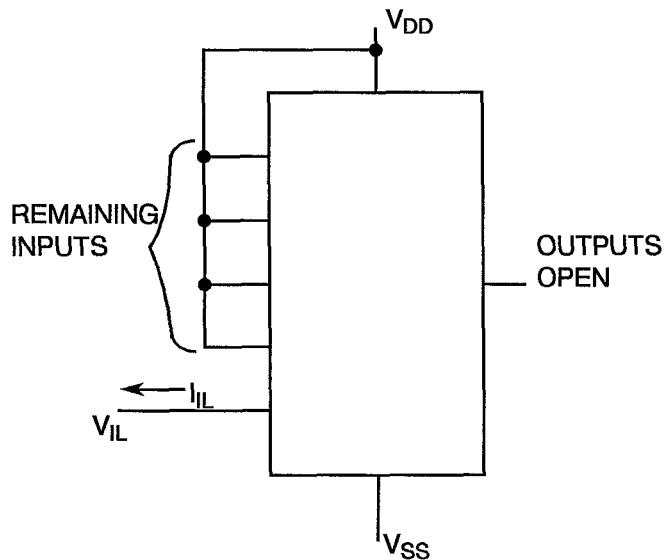
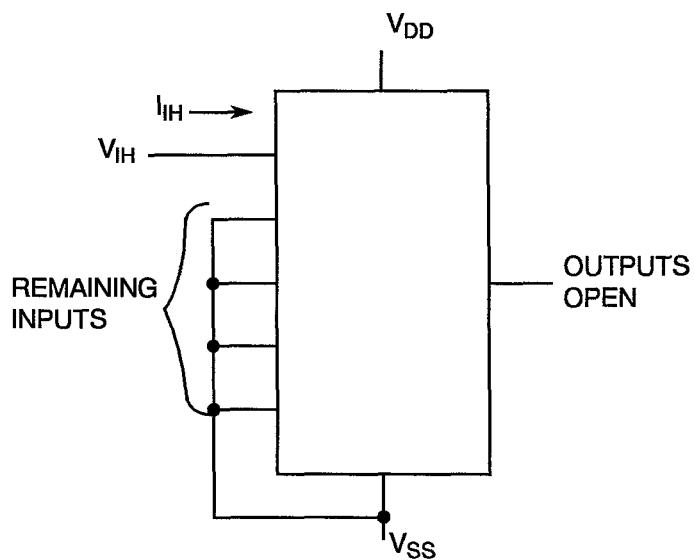
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FIGURE 4 - CIRCUITS FOR ELECTRICAL MEASUREMENTS (CONTINUED)**FIGURE 4(a) - FUNCTIONAL AND QUIESCENT CURRENT TEST TABLE (CONTINUED)**

PATTERN NO.	PIN NUMBERS																							I _{DD} TEST NO.	D.C. SUPPLY		
	1	2	3	4	5	6	7	8	9	10	11	13	14	15	16	17	18	19	20	21	22	23	12	24			
141	0	0	1	0	0	0	0	0	0	1	1	1	1	1	0	1	1	1	1	1	1	0	0	0	0	V _{DD}	
142	0	0	1	0	0	0	0	0	0	0	0	0	0	0	0	0	1	1	1	1	1	1	0	0	0	0	
143	0	0	1	0	0	0	0	0	0	0	0	0	0	0	0	0	1	1	1	1	1	1	0	0	0	0	
144	1	1	1	1	1	1	1	0	0	0	0	0	0	0	1	1	1	1	1	1	1	1	1	1	1	1	
145	1	1	1	1	1	1	1	0	0	0	0	0	0	0	0	1	0	0	0	0	0	1	1	1	1	1	
146	0	0	1	0	0	0	0	0	0	0	0	0	0	0	0	1	1	0	0	0	0	1	0	0	0	0	
147	Z	Z	0	Z	Z	Z	Z	0	0	0	0	0	0	0	0	1	0	1	1	1	1	0	Z	Z	22		
148	Z	Z	0	Z	Z	Z	Z	0	0	0	0	0	0	0	1	1	1	1	1	1	0	Z	Z	23			
149	1	1	1	1	1	1	1	0	0	0	0	0	0	0	1	1	1	1	1	1	1	1	1	1	1	1	

NOTES

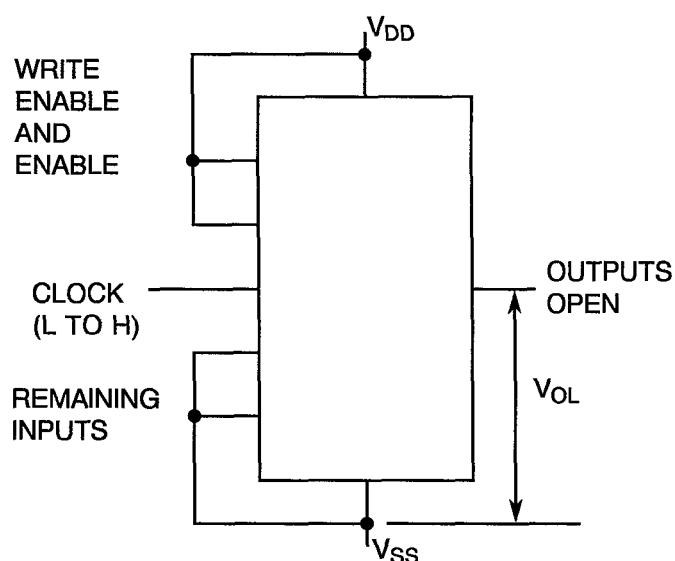
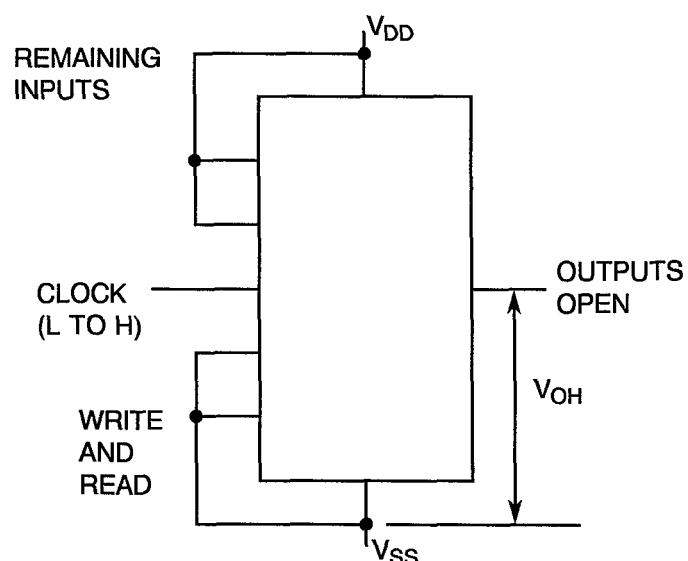
- Figure 4(a) illustrates one series of test patterns. Any other pattern series must be agreed with the Qualifying Space Agency and shall be included as an Appendix.
- Logic Level Definitions: 1 = V_{IH} = V_{DD}, 0 = V_{IL} = V_{SS}, Z=High Impedance.

**FIGURE 4 - CIRCUITS FOR ELECTRICAL MEASUREMENTS (CONTINUED)****FIGURE 4(b) - LOW LEVEL INPUT CURRENT****FIGURE 4(c) - HIGH LEVEL INPUT CURRENT****NOTES**

1. Each input to be tested separately.

NOTES

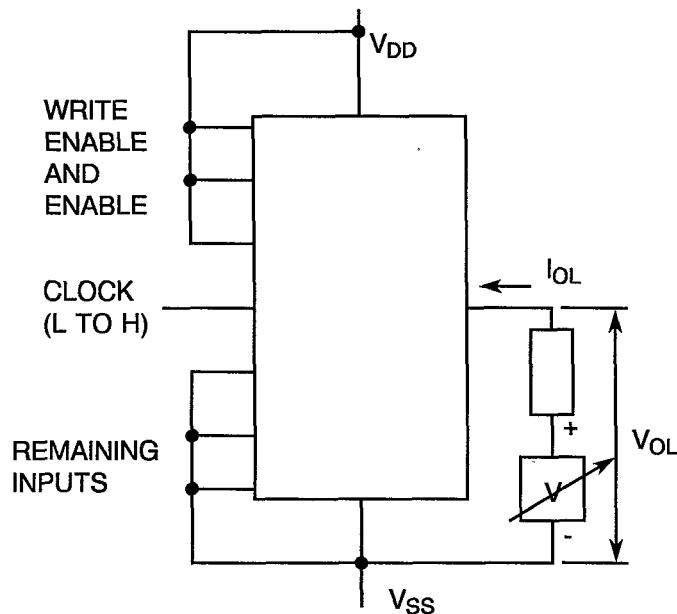
1. Each input to be tested separately.

FIGURE 4(d) - LOW LEVEL OUTPUT VOLTAGE**FIGURE 4(e) - HIGH LEVEL OUTPUT VOLTAGE****NOTES**

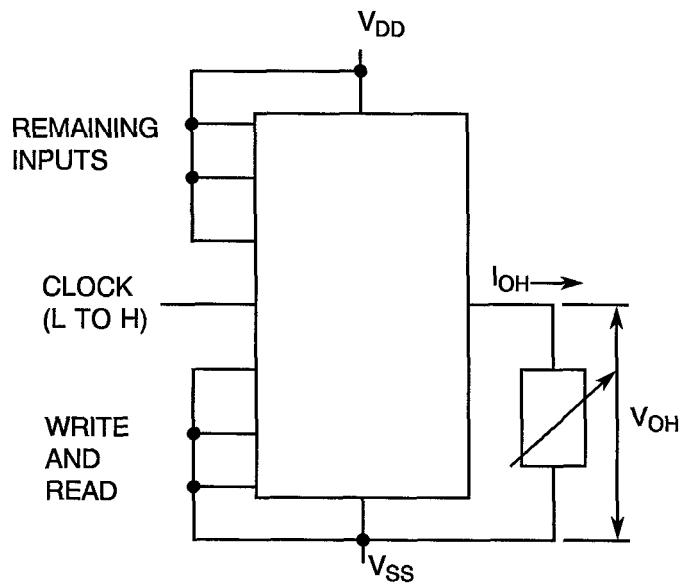
1. Each output to be tested separately.

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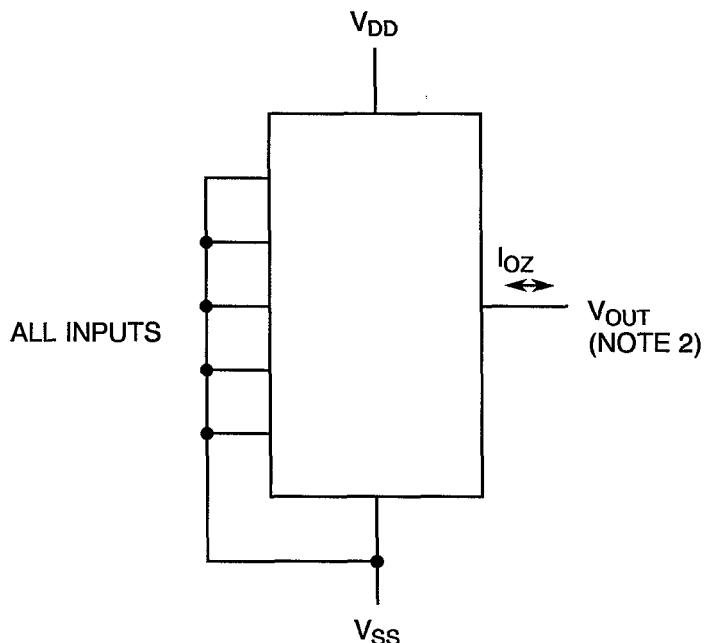
1. Each output to be tested separately.

**FIGURE 4 - CIRCUITS FOR ELECTRICAL MEASUREMENTS (CONTINUED)****FIGURE 4(f) - LOW LEVEL OUTPUT CURRENT****NOTES**

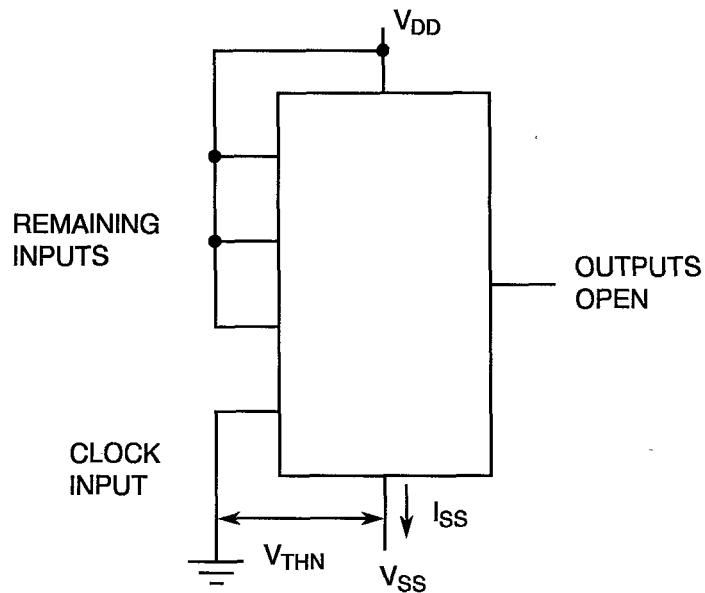
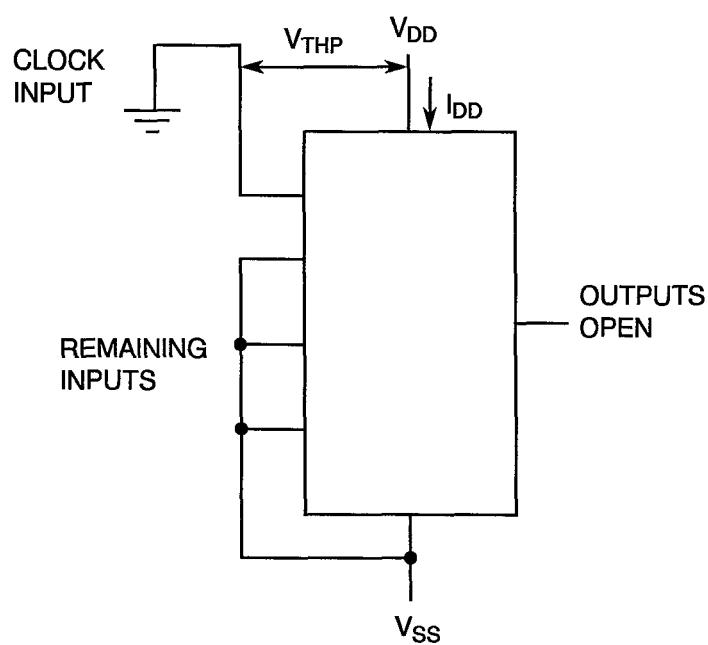
1. Each output to be tested separately.

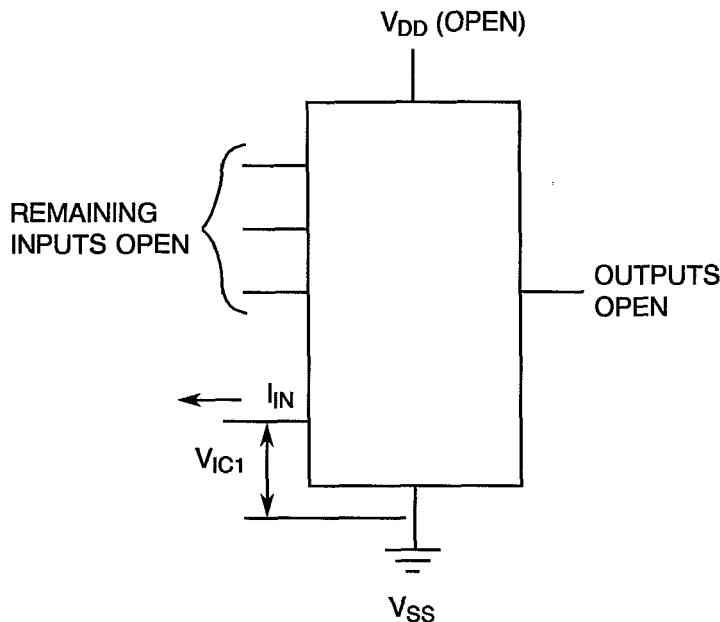
FIGURE 4(g) - HIGH LEVEL OUTPUT CURRENT**NOTES**

1. Each output to be tested separately.

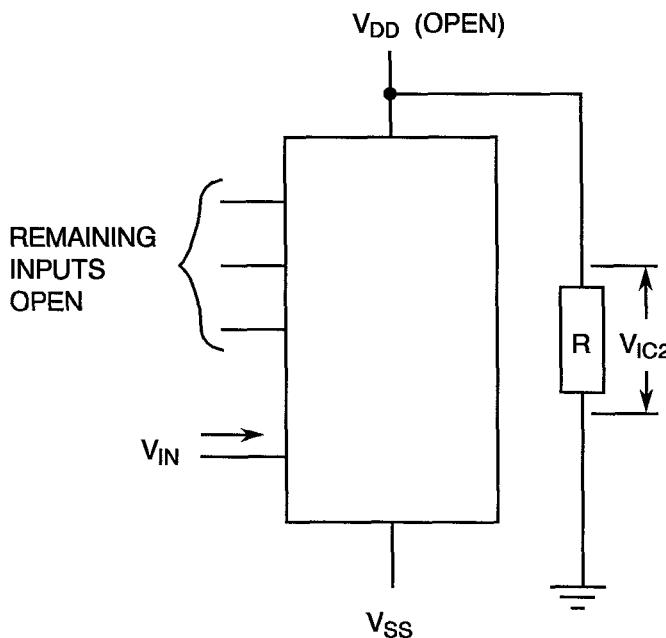
**FIGURE 4 - CIRCUITS FOR ELECTRICAL MEASUREMENTS (CONTINUED)****FIGURE 4(h) - OUTPUT LEAKAGE CURRENT THIRD STATE****NOTES**

1. Each output to be tested separately.
2. I_{OZ} is measured with the following output conditions:
 - (i) Output under test connected to V_{DD} . Remaining outputs open.
 - (ii) Output under test connected to V_{SS} . Remaining outputs open.

**FIGURE 4 - CIRCUITS FOR ELECTRICAL MEASUREMENTS (CONTINUED)****FIGURE 4(i) - THRESHOLD VOLTAGE N-CHANNEL****FIGURE 4(j) - THRESHOLD VOLTAGE P-CHANNEL**

**FIGURE 4 - CIRCUITS FOR ELECTRICAL MEASUREMENTS (CONTINUED)****FIGURE 4(k) - INPUT CLAMP VOLTAGE (V_{SS})****NOTES**

1. Each input to be tested separately.

FIGURE 4(l) - INPUT CLAMP VOLTAGE (V_{DD})**NOTES**

1. Each input to be tested separately.



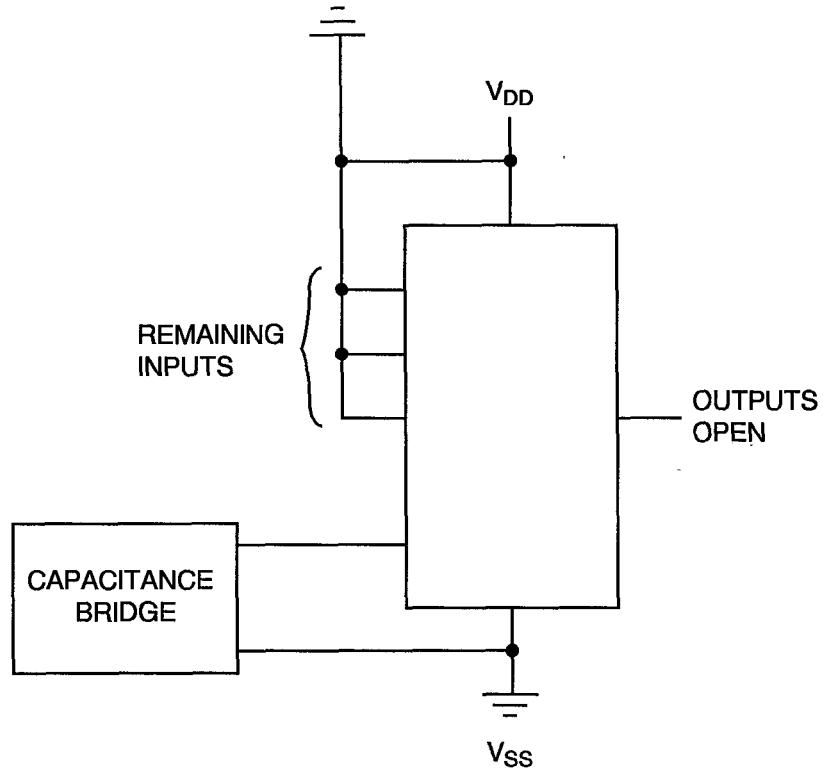
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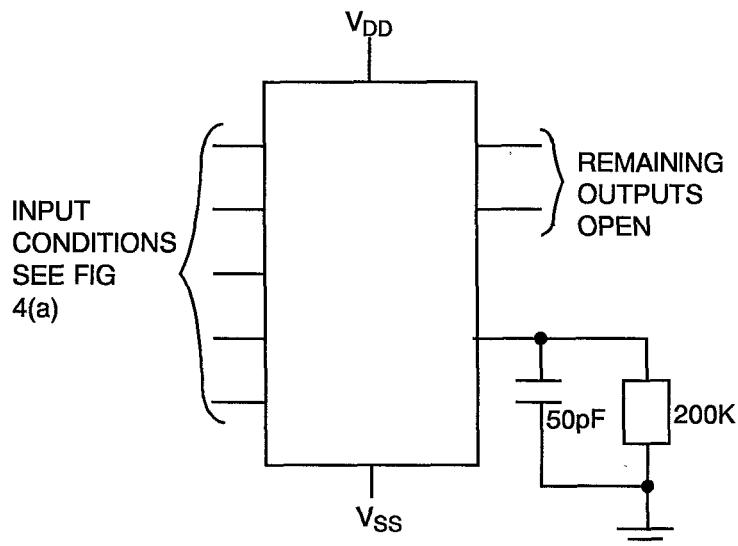
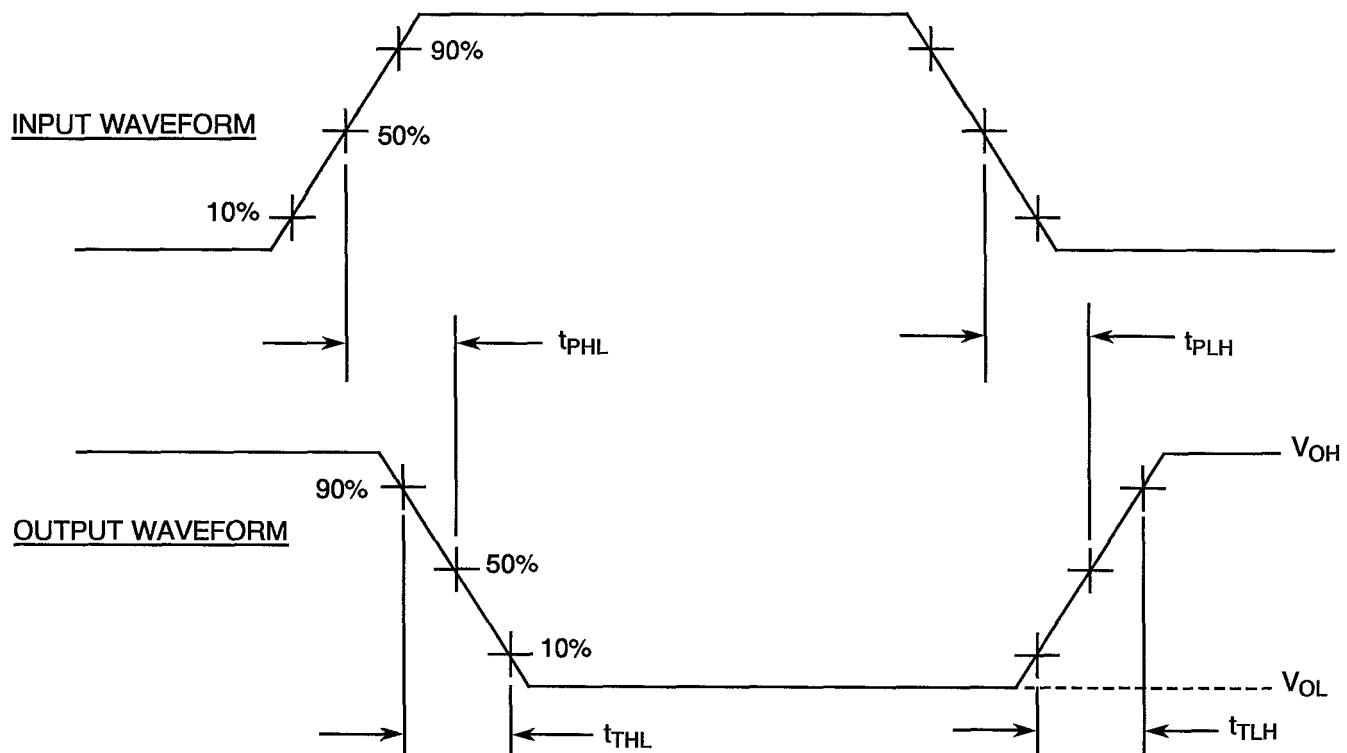
FIGURE 4 - CIRCUITS FOR ELECTRICAL MEASUREMENTS (CONTINUED)

FIGURE 4(m) - INPUT CAPACITANCE

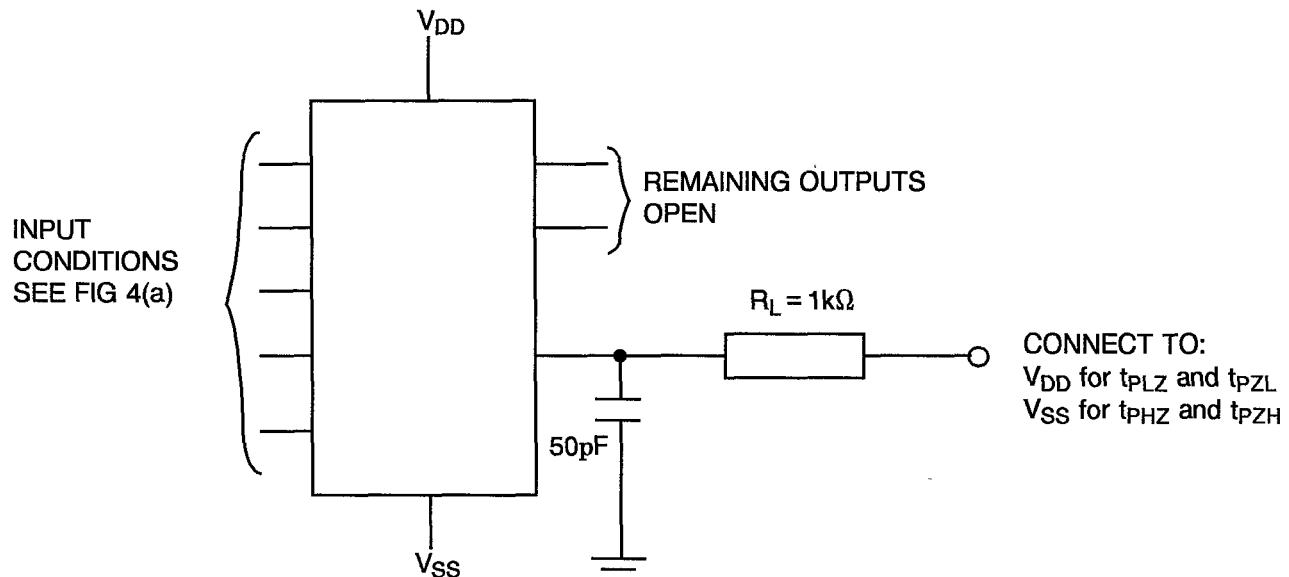
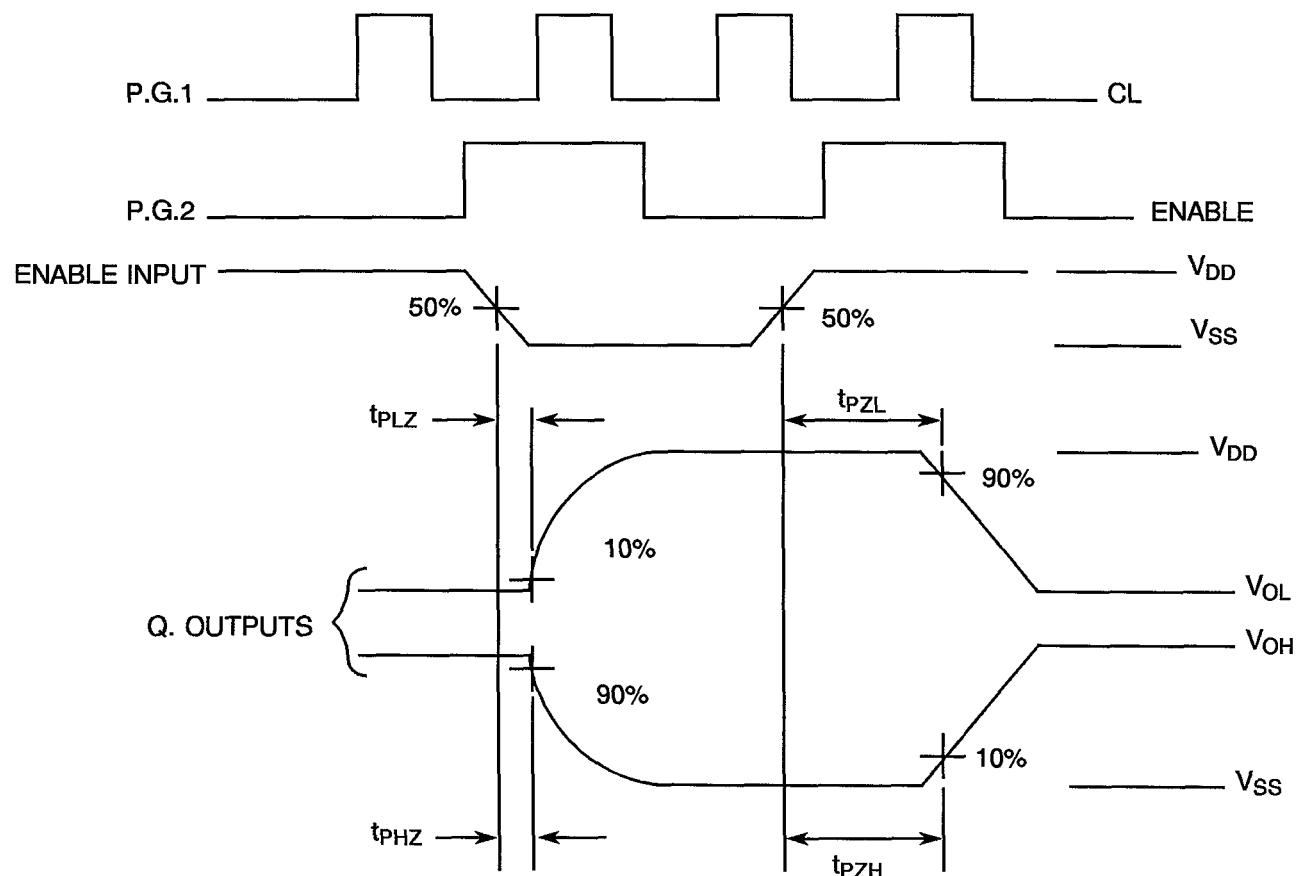


NOTES

1. Each input to be tested separately.
2. $f = 100\text{kHz}$ to 1MHz

**FIGURE 4 - CIRCUITS FOR ELECTRICAL MEASUREMENTS (CONTINUED)****FIGURE 4(n) - PROPAGATION DELAY AND TRANSITION TIME****VOLTAGE WAVEFORMS**

NOTES 1. Pulse Generator - $V_P = 0$ to V_{DD} , t_r and $t_f \leq 15\text{ns}$, $f = 500\text{kHz}$.

**FIGURE 4 - CIRCUITS FOR ELECTRICAL MEASUREMENTS (CONTINUED)****FIGURE 4(o) - PROPAGATION DELAY OUTPUT TO HIGH IMPEDANCE****VOLTAGE WAVEFORM**

NOTES 1. Pulse Generator - $V_P = 0$ to V_{DD} , t_r and $t_f \leq 15\text{ns}$, $f = 500\text{kHz}$.



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ISSUE 2**TABLE 4 - PARAMETER DRIFT VALUES**

NO.	CHARACTERISTICS	SYMBOL	SPEC. AND/OR TEST METHOD	TEST CONDITIONS	CHANGE LIMITS (Δ)	UNIT
3 to 25	Quiescent Current	I_{DD}	As per Table 2	As per Table 2	± 150	nA
70 to 77	Output Drive Current N-Channel	I_{OL1}	As per Table 2	As per Table 2	± 15 (1)	%
86 to 93	Output Drive Current P-Channel	I_{OH1}	As per Table 2	As per Table 2	± 15 (1)	%
102 to 109	Output Leakage Current Third State (1)	I_{OZ1}	As per Table 2	As per Table 2	± 60	nA
110 to 117	Output Leakage Current Third State (2)	I_{OZ2}	As per Table 2	As per Table 2	± 60	nA
120	Threshold Voltage N-Channel	V_{THN}	As per Table 2	As per Table 2	± 0.3	V
121	Threshold Voltage P-Channel	V_{THP}	As per Table 2	As per Table 2	± 0.3	V

NOTES 1. Percentage of limit value if voltage is the measurement function.



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ISSUE 2**TABLE 5(a) - CONDITIONS FOR BURN-IN HIGH TEMPERATURE REVERSE BIAS, N-CHANNELS**

NO.	CHARACTERISTICS	SYMBOL	CONDITION	UNIT
1	Ambient Temperature	T _{amb}	+ 125 (+ 0-5)	°C
2	Outputs - (Pins D/F 1-2-4-5-6-7-22-23) (Pins C 1-2-5-6-7-8-26-27)	V _{OUT}	Open	-
3	Inputs - (Pins D/F 3-9-11-13-15-17-19-21) (Pins C 3-10-13-15-17-20-22-24)	V _{IN}	V _{DD}	Vdc
4	Inputs - (Pins D/F 8-10-14-16-18-20) (Pins C 9-12-16-19-21-23)	V _{IN}	Ground	Vdc
5	Positive Supply Voltage (Pin D/F 24) (Pin C 28)	V _{DD}	15	Vdc
6	Negative Supply Voltage (Pin D/F 12) (Pin C 14)	V _{SS}	Ground	Vdc

NOTES 1. Input Load = Protection Resistor = 2kΩ minimum to 47kΩ maximum.**TABLE 5(b) - CONDITIONS FOR BURN-IN HIGH TEMPERATURE REVERSE BIAS, P-CHANNELS**

NO.	CHARACTERISTICS	SYMBOL	CONDITION	UNIT
1	Ambient Temperature	T _{amb}	+ 125 (+ 0-5)	°C
2	Outputs - (Pins D/F 1-2-4-5-6-7-22-23) (Pins C 1-2-5-6-7-8-26-27)	V _{OUT}	Open	-
3	Inputs - (Pins D/F 3-9-11-13-15-17-19-21) (Pins C 3-10-13-15-17-20-22-24)	V _{IN}	Ground	Vdc
4	Inputs - (Pins D/F 8-10-14-16-18-20) (Pins C 9-12-16-19-21-23)	V _{IN}	V _{DD}	Vdc
5	Positive Supply Voltage (Pin D/F 24) (Pin C 28)	V _{DD}	15	Vdc
6	Negative Supply Voltage (Pin D/F 12) (Pin C 14)	V _{SS}	Ground	Vdc

NOTES 1. Input Load = Protection Resistor = 2kΩ minimum to 47kΩ maximum.



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ISSUE 2**TABLE 5(c) - CONDITIONS FOR BURN-IN DYNAMIC**

NO.	CHARACTERISTICS	SYMBOL	CONDITION	UNIT
1	Ambient Temperature	T_{amb}	+ 125(+ 0-5)	°C
2	Outputs - (Pins D/F 1-2-4-5-6-7-22-23) (Pins C 1-2-5-6-7-8-26-27)	V_{OUT}	$V_{DD}/2$	Vdc
3	Inputs - (Pins D/F 3-15-21) (Pins C 3-17-24)	V_{IN}	V_{DD}	Vdc
4	Inputs - (Pins D/F 8-10-14-16-19-20) (Pins C 9-12-16-19-22-23)	V_{IN}	V_{GEN1}	Vac
5	Inputs - (Pins D/F 9-11-13-17-18) (Pins C 10-13-15-20-21)	V_{IN}	V_{GEN2}	Vac
6	Pulse Voltage	V_{GEN}	0 to V_{DD}	Vac
7	Pulse Frequency Square Wave	f_{GEN1} f_{GEN2}	50k, 50% Duty Cycle 25k, 50% Duty Cycle	Hz
8	Positive Supply Voltage (Pin D/F 24) (Pin C 28)	V_{DD}	15	Vdc
9	Negative Supply Voltage (Pin D/F 12) (Pin C 14)	V_{SS}	Ground	Vdc

NOTES 1. Input Load = Output Load = $2k\Omega$ minimum to $47k\Omega$ maximum.

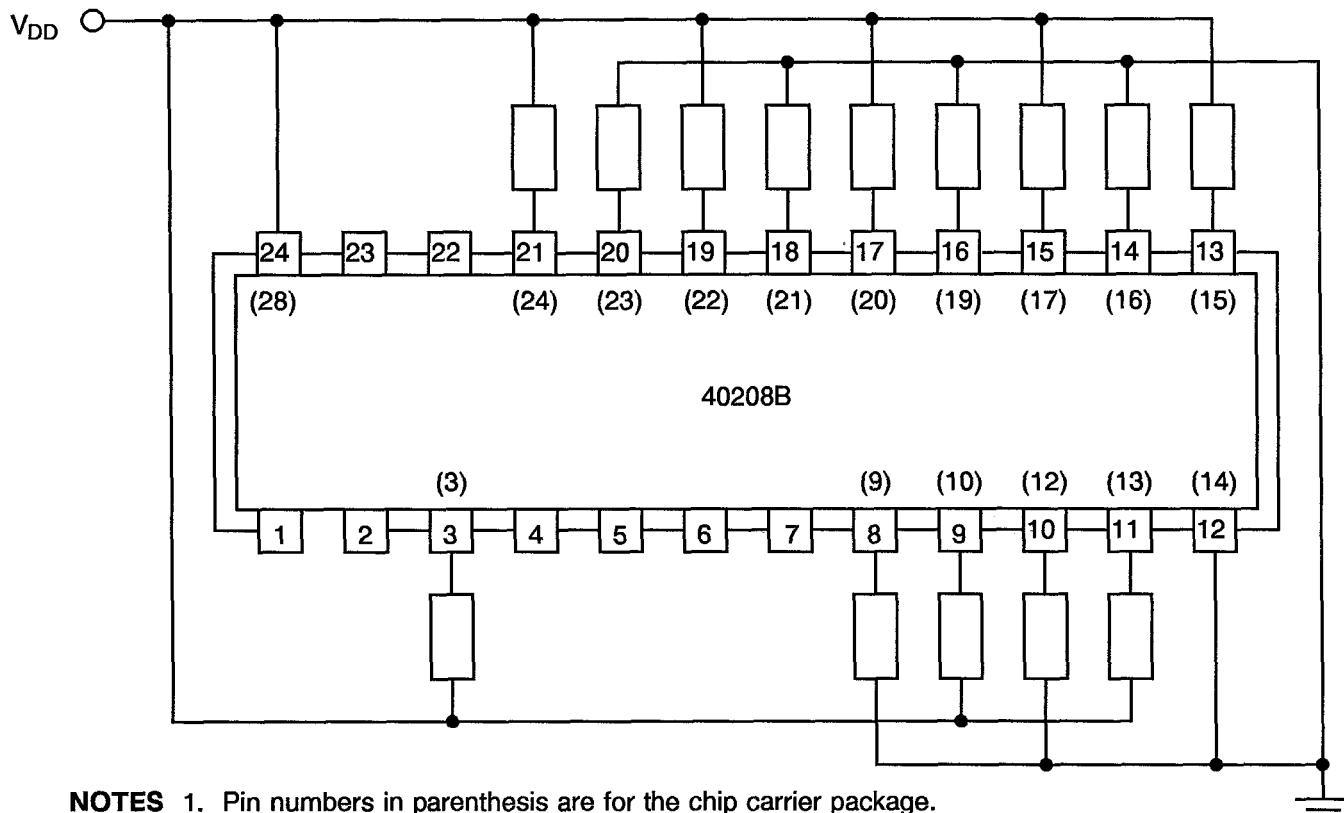
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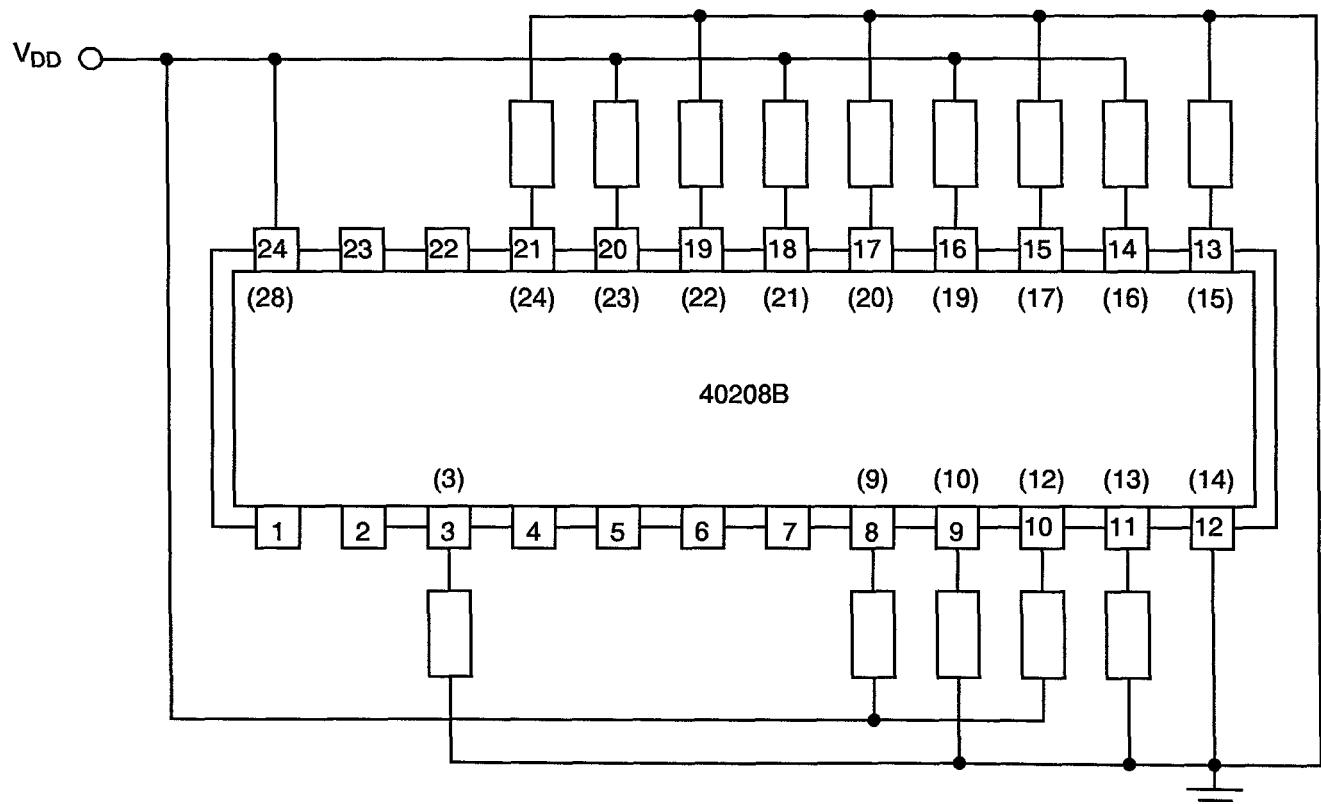
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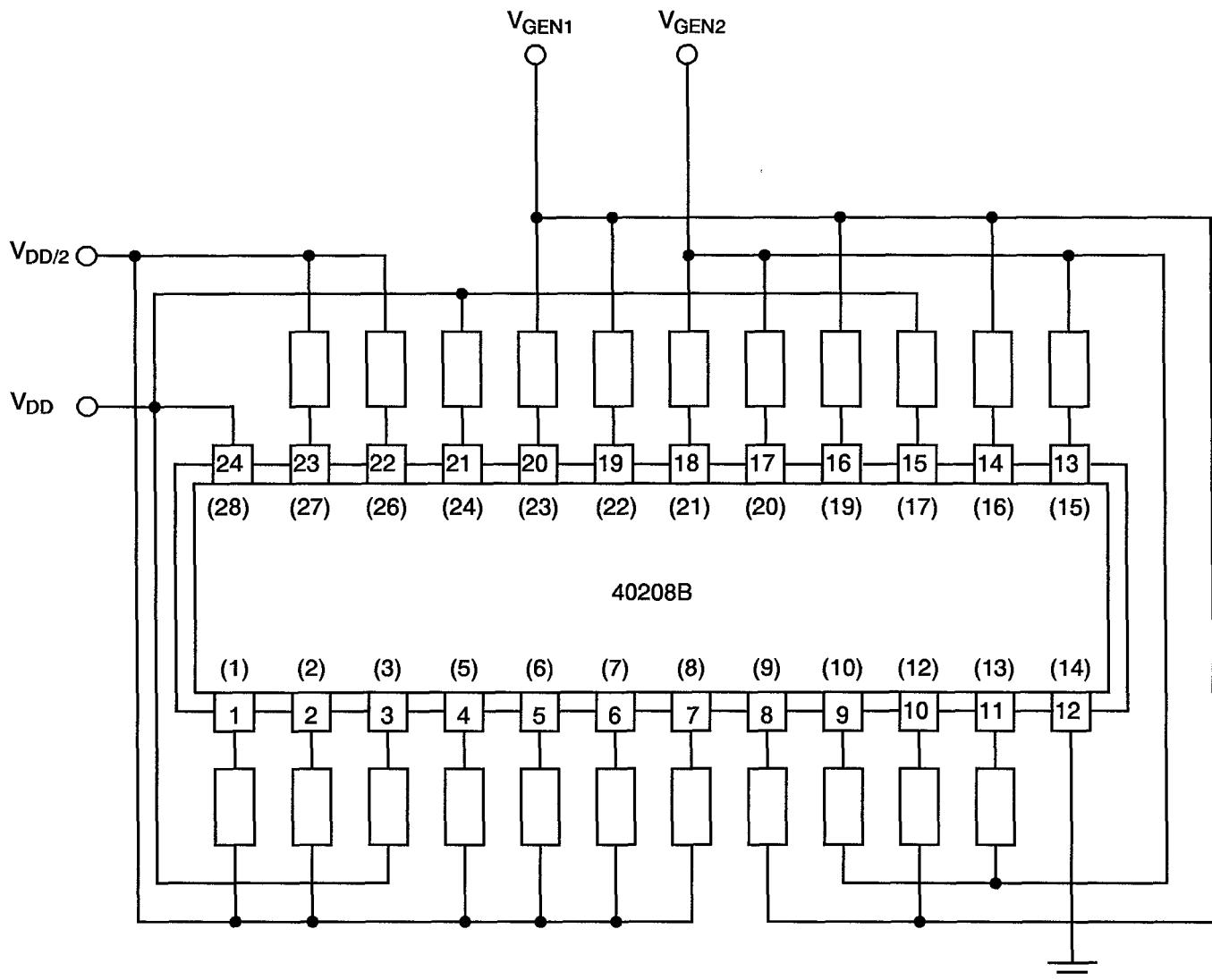
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FIGURE 5(a) - ELECTRICAL CIRCUIT FOR BURN-IN HIGH TEMPERATURE REVERSE BIAS, N-CHANNELS

NOTES 1. Pin numbers in parenthesis are for the chip carrier package.

FIGURE 5(b) - ELECTRICAL CIRCUIT FOR BURN-IN HIGH TEMPERATURE REVERSE BIAS, P-CHANNELS

NOTES 1. Pin numbers in parenthesis are for the chip carrier package.

**FIGURE 5(c) - ELECTRICAL CIRCUIT FOR BURN-IN DYNAMIC**

NOTES 1. Pin numbers in parenthesis are for the chip carrier package.



4.8 ENVIRONMENTAL AND ENDURANCE TESTS

4.8.1 Electrical Measurements on Completion of Environmental Tests

The parameters to be measured on completion of environmental tests are scheduled in Table 6. Unless otherwise stated, the measurements shall be performed at $T_{amb} = +22 \pm 3^{\circ}\text{C}$.

4.8.2 Electrical Measurements at Intermediate Points during Endurance Tests

The parameters to be measured at intermediate points during endurance tests are as scheduled in Table 6 of this specification.

4.8.3 Electrical Measurements on Completion of Endurance Tests

The parameters to be measured on completion of endurance testing are as scheduled in Table 6 of this specification. Unless otherwise stated, the measurements shall be performed at $T_{amb} = +22 \pm 3^{\circ}\text{C}$.

4.8.4 Conditions for Operating Life Test

The requirements for operating life testing are specified in Section 9 of ESA/SCC Generic Specification No. 9000. The conditions for operating life testing shall be as specified in Table 5(c) of this specification.

4.8.5 Electrical Circuits for Operating Life Tests

Circuits for use in performing the operating life tests are shown in Figure 5(c) of this specification.

4.8.6 Conditions for High Temperature Storage Test

The requirements for the high temperature storage test are specified in ESA/SCC Generic Specification No. 9000. The temperature to be applied shall be the maximum storage temperature specified in Table 1(b) of this specification.



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**TABLE 6 - ELECTRICAL MEASUREMENTS ON COMPLETION OF ENVIRONMENTAL TESTS AND AT
INTERMEDIATE POINTS AND ON COMPLETION OF ENDURANCE TESTING**

NO.	CHARACTERISTICS	SYMBOL	SPEC. AND/OR TEST METHOD	TEST CONDITIONS	CHANGE LIMITS (Δ)			UNIT
						MIN	MAX	
1	Functional Test	-	As per Table 2	As per Table 2	-	-	-	-
3 to 25	Quiescent Current	I _{DD}	As per Table 2	As per Table 2	± 150	-	-	nA
26 to 39	Input Current Low Level	I _{IL}	As per Table 2	As per Table 2	-	-	-50	nA
40 to 53	Input Current High Level	I _{IH}	As per Table 2	As per Table 2	-	-	50	nA
54 to 61	Output Voltage Low Level	V _{OL}	As per Table 2	As per Table 2	-	-	0.05	V
62 to 69	Output Voltage High Level	V _{OH}	As per Table 2	As per Table 2	-	14.95	-	V
70 to 77	Output Drive Current N-Channel	I _{OL1}	As per Table 2	As per Table 2	± 15 (1)	-	-	%
78 to 85	Output Drive Current N-Channel	I _{OL2}	As per Table 2	As per Table 2	± 15 (1)	-	-	%
86 to 93	Output Drive Current P-Channel	I _{OH1}	As per Table 2	As per Table 2	± 15 (1)	-	-	%
94 to 101	Output Drive Current P-Channel	I _{OH2}	As per Table 2	As per Table 2	± 15 (1)	-	-	%
102 to 109	Output Leakage Current Third State (1)	I _{OZ1}	As per Table 2	As per Table 2	± 60	-	-	nA
110 to 117	Output Leakage Current Third State (2)	I _{OZ2}	As per Table 2	As per Table 2	± 60	-	-	nA

NOTES 1. Percentage of limit value if voltage is the measurement function.



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ISSUE 2**TABLE 6 - ELECTRICAL MEASUREMENTS ON COMPLETION OF ENVIRONMENTAL TESTS AND AT
INTERMEDIATE POINTS AND ON COMPLETION OF ENDURANCE TESTING (CONTINUED)**

NO.	CHARACTERISTICS	SYMBOL	SPEC. AND/OR TEST METHOD	TEST CONDITIONS	CHANGE LIMITS (Δ)			UNIT
						MIN	MAX	
118	Input Voltage Low Level (Noise Immunity) (Functional Test)	V _{IL1}	As per Table 2	As per Table 2	-	4.5	-	V
	Input Voltage High Level (Noise Immunity) (Functional Test)	V _{IH1}			-	-	0.5	
120	Threshold Voltage N-Channel	V _{THN}	As per Table 2	As per Table 2	± 0.3	-	-	V
121	Threshold Voltage P-Channel	V _{THP}	As per Table 2	As per Table 2	± 0.3	-	-	V

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ISSUE 2**APPENDIX 'A'**

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AGREED DEVIATIONS FOR STMICROELECTRONICS (F)

ITEMS AFFECTED	DESCRIPTION OF DEVIATION
Para. 4.2.3	Para. 9.23, High Temperature Reverse Bias Burn-in: The temperature limits of MIL-STD-883, Para. 4.5.8(c) may be used. Para. 9.24, Power Burn-in: The temperature limits of MIL-STD-883, Para. 4.5.8(c) may be used.
Para. 4.2.4	Para. 9.21.1, Operating Life during Qualification Testing: The temperature limits of MIL-STD-883, Para. 4.5.8(c) may be used.
Para. 4.2.5	Para. 9.21.2, Operating Life during Lot Acceptance Testing: The temperature limits of MIL-STD-883, Para. 4.5.8(c) may be used.